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# LMX2594

SNAS696C - MARCH 2017 - REVISED APRIL 2019

# LMX2594 15-GHz Wideband PLLATINUM<sup>™</sup> RF Synthesizer With Phase Synchronization and JESD204B Support

#### 1 Features

- 10-MHz to 15-GHz output frequency
- -110 dBc/Hz phase noise at 100-kHz offset with 15-GHz carrier
- 45-fs rms jitter at 7.5 GHz (100 Hz to 100 MHz)
- Programmable output power
- PLL key specifications
  - Figure of merit: -236 dBc/Hz
  - Normalized 1/f noise: -129 dBc/Hz
  - High phase detector frequency
    - 400-MHz integer mode
    - 300-MHz fractional mode
  - 32-bit fractional-N divider
- Remove integer boundary spurs with programmable input multiplier
- Synchronization of output phase across multiple devices
- Support for SYSREF with 9-ps resolution programmable delay
- Frequency ramp and chirp generation ability for **FMCW** applications
- < 20-µs VCO calibration speed
- 3.3-V single power supply operation

#### Applications 2

- 5G and mm-Wave wireless infrastructure
- Test and measurement equipment
- Radar
- MIMO
- Phased array antennas and beam forming
- High-speed data converter clocking (supports JESD204B)

## 3 Description

The LMX2594 is a high-performance, wideband synthesizer that can generate any frequency from 10 MHz to 15 GHz without using an internal doubler, thus eliminating the need for sub-harmonic filters. The high-performance PLL with figure of merit of -236 dBc/Hz and high-phase detector frequency can attain very low in-band noise and integrated jitter. The highspeed N-divider has no pre-divider, thus significantly reducing the amplitude and number of spurs. There is also a programmable input multiplier to mitigate integer boundary spurs.

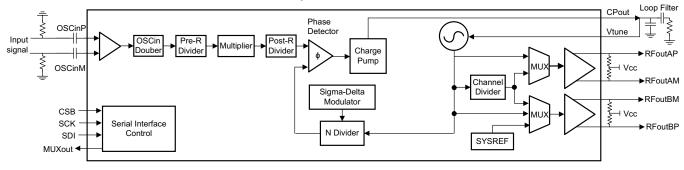
The LMX2594 allows users to synchronize the output of multiple devices and also enables applications that need deterministic delay between input and output. A frequency ramp generator can synthesize up to two segments of ramp in an automatic ramp generation option or a manual option for maximum flexibility. The fast calibration algorithm allows changing frequencies faster than 20 µs. The LMX2594 adds support for generating or repeating SYSREF (compliant to JESD204B standard) designed for low-noise clock sources in high-speed data converters. A fine delay adjustment (9-ps resolution) is provided in this configuration to account for delay differences of board traces.

The output drivers within LMX2594 deliver output power as high as 7 dBm at 15-GHz carrier frequency. The device runs from a single 3.3-V supply and has integrated LDOs that eliminate the need for on-board low noise LDOs.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LMX2594	VQFN (40)	6.00 mm × 6.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



#### **Simplified Schematic**



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# 4 Revision History

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#### Changes from Revision B (March 2018) to Revision C

•	Deleted the recommended bypass capacitor values for Vcc pins 7, 11, 15, 21, 26 and 37, as these capacitor values are not mandatory and the power supply filtering design is up to the user	7
•	Changed all the 'FRAC_ORDER' to 'MASH_ORDER' to avoid confusion	9
•	Changed the names of timing specs to align with timing diagram: changed $t_{CE}$ to $t_{ES}$ , $t_{CS}$ to $t_{DCS}$ , $t_{CH}$ to $t_{CDH}$ , and $t_{CES}$ to $t_{ECS}$ .	. 11
•	Changed the names of timing specs to align with timing diagram: changed $t_{ES}$ to $t_{CE}$ , $t_{CES}$ to $t_{ECS}$ , added $t_{DCS}$ and $t_{CDH}$ , and changed $t_{CS}$ to $t_{CR}$	. 12
•	Changed the serial data input timing diagram and corrected the typo for 'SCK'	12
•	Deleted the note 'The CSB transition from high to low must occur when SCK is low' from the serial data input timing diagram, because SPI mode 4 (CPOL = 1, CPHA = 1) is also supported, and SCK is held high when idle in mode 4	12
•	Added note for the serial data input timing diagram to explain the $t_{CE}$ requirement for mode 4 (CPOL = 1, CPHA = 1) of SPI, because the diagram only indicated SPI mode 1 (CPOL = 0, CPHA = 0)	12
•	Changed the serial data readback timing diagram	13
•	Changed the note about MUXout clocking out and emphasized the effect of t <sub>CR</sub> on the readback data available time	13
•	Changed the $f_{OUT}$ test conditions in the <i>Closed-Loop Phase Noise at 3.5 GHz</i> graph from: 14 GHz / 2 = 3.5 GHz to: to 14 GHz / 4 = 3.5 GHz	15
•	Added Normalized Output Power Across OUTA_PWR With Resistor Pullup graph	
•	Changed "Vtune" to "Indirect Vtune" when LD_TYPE = 1	
•	Changed description for LD_TYPE.	
•	Added description of Indirect Vtune.	. 22
•	Added description for the 'no assist' mode, mphasized the effect of VCO_SEL, VCO_DACISET_STRT and VCO_CAPCTRL_STRT under 'no assist' mode, and added recommended values for these registers	23
•	Added description for the 'full assist' mode to allow the user to set VCO amplitude and capcode using linear interpolation under certain conditions	23
•	Changed OUTx_PWR Recommendations for Resistor Pullup table	
•	Added description for category 3 of SYNC feature stating that FCAL_EN needs to be 1	
•	Changed description of MASH_SEED	



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# **Revision History (continued)**

•	Added 10-ms wait time before re-programming register R0 in recommended initial power-up sequence 4	10
•	Added the General Programming Requirements section based on frequently asked questions	0
•	Changed register R4 in the register map to: exposed ACAL_CMP_DLY 4	1
•	Changed the register R20[14] value from 0 to 1 in the full register map to match the R20 register description 4	1
•	Changed the default value of R25 to align with register map of LMX2595. This change has no impact on the LMX2594. 4	2
•	Changed the R0[14] register field name in the register map from VCO_PHASE_SYNC_EN to VCO_PHASE_SYNC. to align with the rest of the data sheet	16
•	Added recommended value for register CAL_CLK_DIV when lock time is not of concern	6
•	Changed the typo for register 'VCO_DACISET' in the register map. Bit 0 of this register was not included in the map. The full register map and register description were correct	18
•	Added description to the R4[15:8]: ACAL_CMP_DLY register 4	8
•	Deleted the bit description '0: disabled; 1: enabled' for register 'PLL_N' 4	9
•	Added description to the R60[15:0] LD_DLY register	<b>51</b>
•	Changed the R31[14] register name from CHDIV_DIV2 to SEG1_EN to align with the naming in the TICS Pro GUI 5	<b>i</b> 3
•	Changed the R105[1:0] field name from RAMP_NEXT_TRIG to RAMP1_NEXT_TRIG	<b>5</b> 8
•	Added the Bias Levels of Pins table	<b>5</b> 4

#### Changes from Revision A (August 2017) to Revision B

#### Page

•	Changed all the VCO Gain typical values in the <i>Electrical Characteristics</i> table. This is due to improved measurement methods and NOT a change in the device itself	. 11
•	Moved the high-level output voltage parameter $V_{CC}$ – 0.4 value from the MAX column to the MIN	. 11
•	Moved the high-level output current parameter 0.4 value from the MIN column to the MAX	. 11
•	Changed bulleted text: data is clocked out on MUXout, not SDI pin	. 13
•	Added comment that OSCin is clocked on rising edges of the signal. and reformatted with bulleted list	. 19
•	Added description of the state machine clock	. 20
•	Changed example from: 200 MHz / 2 <sup>32</sup> to: 200 MHz / (2 <sup>32</sup> – 1)	. 21
•	Changed LD_DLY description in Table 4 and removed duplicated text in the Lock Detect section	. 21
•	Changed name from VCO_AMPCAL to VCO_DACISET_STRT	. 23
•	Added more programmable settings to Table 5	. 23
•	Changed VCO Gain table	24
•	Added that OUTx_PWR states 32 to 47 are redundant and reworded section	. 25
•	Added term "IncludedDivide" for clarity	. 26
•	Changed Fixed Diagram to show SEG0, SEG1, SEG2, and SEG3	. 27
•	Changed included channel divide to IncludedDivide and 2 X SEG0 to 2 X SEG1. Also clarified IncludedDivide	
	calculations	
•	Added more description on conditions for phase adust	
•	Changed text from: (VCO_PHASE_SYNC = 1) to: (VCO_PHASE_SYNC = 0)	
•	Changed text so the user does not incorrectly assume that MASH_SEED varies from part ot part	
•	Changed the RAMP_THRESH programming from: 0 to $\pm 2^{32}$ to: 0 to $\pm 2^{33} - 1$	. 30
•	Removed comment that RAMP_TRIG_CAL only applies in automatic ramping mode	
•	Changed the RAMP_LOW and _HIGH programming from: 0 to $\pm 2^{31}$ to: 0 to $\pm 2^{33} - 1$	. 30
•	Changed description to be in terms of state machine cycles	. 31
•	Changed RAMP_MODE to RAMP_MANUAL in the Manual Pin Ramping and Automatic Ramping sections	. 31
•	Added that the RampCLK pin input is reclocked to the phase detector frequency	. 31
•	Added that RampDir rising edges should be targeted away from rising edges of RampCLK pin	. 31
•	Changed programming enumerations for RAMP0_INC and RAMP1_INC	. 33

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•	Changed programming enumerations for RAMP_THRESH, RAMPx_LEN, and RAMP1_INC	. 34
•	Changed Figure 29	. 34
•	Changed SysRef description	. 35
•	Added divide by 2 to figure	. 35
•	Changed some entries in the table	. 35
•	Changed f <sub>INTERPOLATOR</sub> SYSREF setup equation in Table 18	. 35
•	Changed SysRef delay from: 224 and 225 to: 225 and 226	. 36
•	Changed "generator" mode to "master" mode. They mean the same thing	. 36
•	Changed description for SYSREF_DIV	. 36
•	Changed Figure 31	. 37
•	Changed wording for repeater mode and master mode	. 38
•	Changed description of a few of the steps	. 39
•	Changed typo in R17 and R19	. 48
•	Deleted reference to VCO_SEL_STRT_EN. This is always 1	. 48
•	Added VCO_SEL_STRT_EN reference. This is always 1	. 48
•	Changed the enumerations 0-3 and added content to the INPIN_LVL field description	. 50
•	Added Divide by 1' to SYSREF_DIV_PRE register description. Also fixed the name misspelling	. 52
•	Deleted redundant formula for Fout and also clarified SYSREF_DIV starts at 4 and counts by 2	. 52
•	Deleted reference to VCO_CAPCTRL_EN, which is always 1, and clarified	. 54
•	Changed text from: f <sub>MAX</sub> to: f <sub>HIGH</sub>	. 55
•	Changed text from: RAMP_LIMIT_LOW= $2^{32}$ - (f <sub>LOW</sub> - f <sub>VCO</sub> ) / f <sub>PD</sub> × 16777216 to: RAMP_LIMIT_LOW= $2^{33}$ - 16777216 x (f <sub>VCO</sub> - f <sub>LOW</sub> ) / f <sub>PD</sub>	55
•	Removed the OSCin Configuration table and added content to the OSCin Configuration section	
•	Changed pin 27 recommendation from 10 µF to 1 µF in Figure 51	

# Changes from Original (March 2017) to Revision A

4	Submit Documentation Feedback Copyright © 2017–2019, Texas Instruments Inco	rporated
•	Added INPIN_IGNORE, INPIN_LVL, and INPIN_HYST	43
•	Added SEG1_EN	42
•	Added recommendation to make f <sub>Interpolator</sub> a multiple of f <sub>OSC</sub>	39
•	Changed SysRef Example Description and Pictures	38
•	Added SYSREF_EN = 1 if and only if OUTB_MUX=2	36
•	Changed graphic and description	35
•	Added section on fine tune adjustments	30
•	Changed the IncludedDivide table	26
•	Added Recommendations table	25
•	Changed table to allow 11.5 GHz max frequency for divides >6	
•	Moved second paragraph of <i>Readback</i> into <i>Lock Detect</i> section; deleted last paragraph of <i>Readback</i> (was in wrong place)	
•	Added Phase noise vs. Fpd Graph	16
•	Added Phase Noise plots vs. Temperature	
•	Added 12-GHz VCO frequency for PLL Noise Metrics Plot	
•	Added graphs and reordered	
•	Swapped SDI and SCK in diagram	
•	Changed "SDA" pin name mispelled. Should be "SDI". Also fixed in timing diagrams. Also added CE Pin	11
•	Clarified that output power assumes that load is matched and losses are de-embedded	9
•	Added H2 Spec for 11 GHz	9
•	Added DAP pin described as "Die Attach Pad"	



STRUMENTS

**EXAS** 

# Page

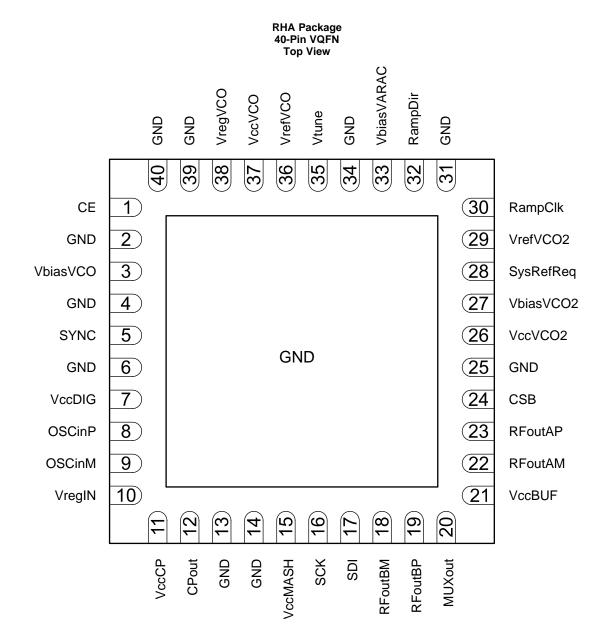


#### LMX2594 SNAS696C – MARCH 2017 – REVISED APRIL 2019

•	Removed RAMP0_FL from register map	45
•	Changed address for VCO_DACISET_STRT and VCO_CAPCTRL	48
•	Clarified MASH_RESET_N. 0 = RESET (integer mode), 1 = Fractional mode	49
•	Changed OUT_ISEL to OUTI_SET	
•	Added SYSREF_EN=1 when OUTB_MUX=2	50
•	Added section for input register descriptions	
•	Added description for SEG1_EN	53
•	Fixed TYPO table to match main register map.	
•	Added SEG1_EN	
•	Corrected RAMP_BURST_TRIG description to match other place in data sheet	56
•	Removed duplicate error in R101[2]	57
•	Changed RAMP1_INC from RAMP0 to RAMP1	57
•	Clarified that the delay was in state machine cycles	
•	Swapped 1 and 3 in the R110[10:9] description	
•	Fixed pin names in schematic	



# 5 Pin Configuration and Functions





## **Pin Functions**

	PIN				
NO. NAME		I/O	DESCRIPTION		
1	CE	Input	Chip enable input. Active HIGH powers on the device.		
2, 4, 25, 31, 34, 39, 40	GND	Ground	VCO ground.		
3	VbiasVCO	Bypass	VCO bias. Requires a 10-µF capacitor connected to VCO ground. Place close to pin.		
5	SYNC	Input	Phase synchronization pin. Has programmable threshold.		
6, 14	GND	Ground	Digital ground.		
7	VccDIG	Supply	Digital supply. TI recommends bypassing with decoupling capacitor to digital ground.		
8	OSCinP	Input	Reference input clock (+). High-impedance self-biasing pin. Requires AC-coupling capacitor. (0.1 $\mu$ F recommended)		
9	OSCinM	Input	Reference input clock (–). High impedance self-biasing pin. Requires AC-coupling capacitor. (0.1 $\mu F$ recommended)		
10	VregIN	Bypass	Input reference path regulator output. Requires a $1-\mu F$ capacitor connected to ground. Place close to pin.		
11	VccCP	Supply	Charge pump supply. TI recommends bypassing with decoupling capacitor to charge pump ground.		
12	CPout	Output	Charge pump output. TI recommends connecting C1 of loop filter close to pin.		
13	GND	Ground	Charge pump ground.		
15	VccMASH	Supply	Digital supply. TI recommends bypassing with decoupling capacitor to digital ground.		
16	SCK	Input	SPI clock. High impedance CMOS input. 1.8-V to 3.3-V logic.		
17	SDI	Input	SPI data. High impedance CMOS input. 1.8-V to 3.3-V logic.		
18	RFoutBM	Output	Differential output B (–). Requires a pullup (typically 50- $\Omega$ resistor) connected to Vcc as close to the pin as possible. Can be used as an output signal or SYSREF output.		
19	RFoutBP	Output	Differential output B (+). Requires a pullup (typically 50- $\Omega$ resistor) connected to Vcc as close o the pin as possible. Can be used as an output signal or SYSREF output.		
20	MUXout	Output	lultiplexed output pin — lock detect, readback, diagnostics, ramp status.		
21	VccBUF	Supply	Output buffer supply. TI recommends bypassing with decoupling capacitor to RFout ground.		
22	RFoutAM	Output	Differential output A (–). Requires connecting a 50- $\Omega$ resistor pullup to Vcc as close to the pin as possible.		
23	RFoutAP	Output	Differential output A (+). Requires connecting a 50- $\Omega$ resistor pullup to Vcc as close to the pin as possible.		
24	CSB	Input	SPI latch. Chip Select Bar. High-impedance CMOS input. 1.8-V to 3.3-V logic.		
26	VccVCO2	Supply	VCO supply. TI recommends bypassing with decoupling capacitor to VCO ground.		
27	VbiasVCO2	Bypass	VCO bias. Requires a 1-µF capacitor connected to VCO ground.		
28	SysRefReq	Input	SYSREF request input for JESD204B support.		
29	VrefVCO2	Bypass	VCO supply reference. Requires a 10-µF capacitor connected to VCO ground.		
30	RampClk	Input	Input pin for ramping mode that can be used to clock the ramp in manual ramping mode or as a trigger input.		
32	RampDir	Input	Input pin for ramping mode that can be used to change ramp direction in manual ramping mode or as a trigger input.		
33	VbiasVARAC	Bypass	VCO Varactor bias. Requires a 10-µF capacitor connected to VCO ground.		
35	Vtune	Input	VCO tuning voltage input.		
36	VrefVCO	Bypass	VCO supply reference. Requires a 10-µF capacitor connected to VCO ground.		
37	VccVCO	Supply	VCO supply. Recommend bypassing with decoupling capacitor to ground.		
38	VregVCO	Bypass			
DAP	GND	Ground	Die Attached Pad. Used for RFout ground.		

## 6 Specifications

## 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
V <sub>CC</sub>	Power supply voltage	-0.3	3.6	V
TJ	Junction temperature	-40	150	°C
T <sub>stg</sub>	Storage temperature	-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 6.2 ESD Ratings

			VALUE	UNIT	
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000		
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±750	V	

(1) JEDEC document JEP155 states that 500 V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500 V HBM is possible with the necessary precautions. Pins listed as ±XXX V may actually have higher performance.

(2) JEDEC document JEP157 states that 250 V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250 V CDM is possible with the necessary precautions. Pins listed as ±YYY V may actually have higher performance.

## 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Power supply voltage	3.15	3.3	3.45	V
T <sub>A</sub>	Ambient temperature	-40	25	85	°C
TJ	Junction temperature			125	°C

## 6.4 Thermal Information

		LMX2594	
	THERMAL METRIC <sup>(1)</sup>	RHA (VQFN)	UNIT
		40 PINS	
$R_{ hetaJA}$	Junction-to-ambient thermal resistance	30.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance <sup>(2)</sup>	15.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	5.4	°C/W
ΨJT	Junction-to-top characterization parameter	0.2	°C/W
Ψјв	Junction-to-board characterization parameter	5.3	°C/W
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	0.9	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report (SPRA953).

(2) DÁP



#### 6.5 Electrical Characteristics

 $3.15 \text{ V} \le \text{V}_{CC} \le 3.45 \text{ V}, -40^{\circ}\text{C} \le \text{T}_{A} \le +85^{\circ}\text{C}.$  Typical values are at  $\text{V}_{CC} = 3.3 \text{ V}, 25^{\circ}\text{C}$  (unless otherwise noted).

	PARAMETER	TEST CO	ONDITIONS	MIN	TYP	MAX	UNIT	
POWER \$	SUPPLY							
V <sub>CC</sub>	Supply voltage			3.15	3.3	3.45	V	
I <sub>CC</sub>	Supply current	OUTA_PD = 0, OUTB_PD = 1 OUTA_MUX = OUTB_MUX = 1 OUTA_PWR = 31, CPG=7 $f_{OSC} = f_{PD} = 100 \text{ MHz}, f_{VCO} = f_{OUT} = 14 \text{ GHz}$ $p_{OUT} = 3 \text{ dBm with } 50-\Omega \text{ resistor pullup}$			340		mA	
	Power-on reset current	RESET=1			170			
	Power-down current	POWERDOWN=1		5				
OUTPUT	CHARACTERISTICS					·		
		50-Ω resistor pullup	f <sub>OUT</sub> = 8 GHz		5			
~	Single-ended output $power^{(1)(2)}$	OUTx_PWR = 50	f <sub>OUT</sub> = 15 GHz		2		dDm	
Роит		1-nH inductor pullup	f <sub>OUT</sub> = 8 GHz		10		dBm	
		OUTx_PWR = 50	f <sub>OUT</sub> = 15 GHz		7			
Xtalk	Isolation between outputs A and B. Measured on output A	OUTA_MUX = VCO OUTB_MUX = channel	divider		-50		dBc	
	<b>2</b> (2)	OUTA_MUX = VCO f <sub>VCO</sub> = 8 GHz			-20			
H2	Second harmonic <sup>(2)</sup>	OUTA_MUX = VCO f <sub>VCO</sub> = 11 GHz			-30		dBc	
H3	Third harmonic <sup>(2)</sup>	OUTA_MUX = VCO f <sub>VCO</sub> = 8 GHz			-50		dBc	
INPUT SI	GNAL PATH	100						
	54	$OSC_2X = 0$		5		1400	MHz	
f <sub>OSCin</sub>	Reference input frequency	OSC_2X = 1		5		200		
VOSCin	Reference input voltage	AC-coupled required (3)		0.2		2	Vpp	
	Multiplier frequency (only	Input range		30		70		
f <sub>MULT</sub>	applies when multiplier is enabled)	Output range		180		250	MHz	
PHASE D								
		Integer mode	MASH_ORDER = 0	0.125		400		
f <sub>PD</sub>	Phase detector frequency <sup>(3)</sup>	Fractional mode	MASH_ORDER= 1, 2, 3	5		300	MHz	
			MASH_ORDER = 4	5		240		
	Charge-pump leakage current	CPG = 0			15		nA	
		CPG = 4			3			
	Effective charge pump current.	CPG = 1			6			
I <sub>CPout</sub>	This is the sum of the up and	CPG = 5		9			mA	
	down currents	CPG = 3		12				
		CPG = 7			15			
PN <sub>PLL_1/f</sub>	Normalized PLL 1/f noise		$2 \cap U_{-}(4)(4)(4)(4)(4)$		-129		dBc/Hz	
PN <sub>PLL_flat</sub>	Normalized PLL noise floor	$f_{PD} = 100 \text{ MHz}, f_{VCO} = 1$			-236		dBc/Hz	

(1) Single ended output power obtained after de-embedding microstrip trace losses and matching with a manual tuner. Unused port terminated to 50 ohm load.

Output power, spurs, and harmonics can vary based on board layout and components. (2)

(3) For lower VCO frequencies, the N divider minimum value can limit the phase-detector frequency.

The PLL noise contribution is measured using a clean reference and a wide loop bandwidth and is composed into flicker and flat components. PLL\_flat = PLL\_FOM + 20 x log(Fvco/Fpd) + 10 x log(Fpd / 1Hz). PLL\_flicker (offset) = PLL\_flicker\_Norm + 20 x log(Fvco / 1GHz) - 10 x log(offset / 10kHz). Once these two components are found, the total PLL noise can be calculated as PLL\_Noise =  $10 \times \log(10^{PLL_Flat / 10} + 10^{PLL_flicker / 10})$ (4)



# **Electrical Characteristics (continued)**

3.15 V  $\leq$  V<sub>CC</sub>  $\leq$  3.45 V, -40°C  $\leq$  T<sub>A</sub>  $\leq$  +85°C. Typical values are at V<sub>CC</sub> = 3.3 V, 25°C (unless otherwise noted).

PARAMETER	TEST CO	NDITIONS	MIN TYP MAX	UNIT
VCO CHARACTERISTICS				
		10 kHz	-80	
		100 kHz	-107	_
	VCO1 f <sub>VCO</sub> = 8 GHz	1 MHz	-128	
		10 MHz	-148	
		90 MHz	-157	
		10 kHz	-79	
		100 kHz	-105	
	VCO2 f <sub>VCO</sub> = 9.2 GHz	1 MHz	-127	
		10 MHz	-147	
		90 MHz	-157	
		10 kHz	-77	
		100 kHz	-104	
	VCO3 f <sub>VCO</sub> = 10.3 GHz	1 MHz	-126	
	$V_{CO} = 10.3 \text{ GHz}$	10 MHz	-147	
		90 MHz	-157	
		10 kHz	-76	76           03           25           45           58           74           00
		100 kHz	-103	
N <sub>VCO</sub> VCO phase noise		1 MHz	-125	
	f <sub>VCO</sub> = 11.3 GHz	10 MHz	-145	
		90 MHz	-158	
		10 kHz	-74	
		100 kHz	-100	
		1 MHz	-123	
	f <sub>VCO</sub> = 12.5 GHz	10 MHz	-144	
		90 MHz	-157	7         9         5         7         7         7         7         7         7         4         6         7         6         3         5         8         4         0         3         4         0         3         2         3         9         1         3         2         0         5         3         9         1         3         2         0         5         3         9         1         3         2         0         5         3         9         1         3         2         0         5         0         5         0         5         0 <t< td=""></t<>
		10 kHz	-73	
		100 kHz	-100	
		1 MHz	-122	
	f <sub>VCO</sub> = 13.3 GHz	10 MHz	-143	
		90 MHz	-155	
		10 kHz	-73	
		100 kHz	-99	
	VCO7 f <sub>VCO</sub> = 14.5 GHz	1 MHz	-121	
	1VCO = 14.0 GHZ	10 MHz	-143	
		90 MHz	-152	
	Quiteb errors that a fi	No assist	50	
	Switch across the entire frequency band	Partial assist	35	
COCAL VCO calibration speed	$f_{OSC} = 200 \text{ MHz}, f_{PD} = 100 \text{ MHz}^{(5)}$	Close frequency	20	μs
	100 MHz <sup>(5)</sup>	Full assist	5	

(5) See Application and Implementation for more details on the different VCO calibration modes.



#### **Electrical Characteristics (continued)**

 $3.15 \text{ V} \le \text{V}_{CC} \le 3.45 \text{ V}, -40^{\circ}\text{C} \le \text{T}_{A} \le +85^{\circ}\text{C}.$  Typical values are at  $\text{V}_{CC} = 3.3 \text{ V}, 25^{\circ}\text{C}$  (unless otherwise noted).

	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT	
		8 GHz			92			
		9.2 GHz		91				
		10.3 GHz			115			
K <sub>VCO</sub>	VCO gain	11.3 GHz			121		MHz/V	
		12.5 GHz			195			
		13.3 GHz 14.5 GHz			190	°C           dBc           100           MHz           Vcc           Vcc           V	190	
					213			
$ \Delta T_{CL} $	Allowable temperature drift when VCO is not recalibrated	RAMP_EN = 0 or RAMP_	RAMP_EN = 0 or RAMP_MANUAL= 1		125		°C	
H2	VCO second harmonic	f <sub>VCO</sub> = 8 GHz, divider dis	f <sub>VCO</sub> = 8 GHz, divider disabled		-20		dD a	
H3	VCO third haromonic	f <sub>VCO</sub> = 8 GHz, divider disabled			-50		abc	
SYNC PI	N AND PHASE ALIGNMENT							
f <sub>OSCin</sub> SY	Maximum usable OSCin with	Category 3		0		100		
NC	sync pin (Figure 27)	Categories1 and 2		0		1400	INILIZ	
	INTERFACE o SLK, SDI, CSB, CE, RampDir,	RampClk, MUXout, SYNC	C (CMOS Mode), SysRefR	eq (CMOS Moc	le)			
V <sub>IH</sub>	High-level input voltage			1.4		Vcc	V	
V <sub>IL</sub>	Low-level input voltage			0		0.4	V	
I <sub>IH</sub>	High-level input current			-25		25	μA	
I <sub>IL</sub>	Low-level input current			-25		25	μA	
V <sub>OH</sub>	High-level output voltage	MUVout nin	Load current = -10 mA	$V_{CC} - 0.4$			V	
V <sub>OL</sub>	Low-level output voltage	MUXout pin	Load current = 10 mA			0.4	V	

## 6.6 Timing Requirements

 $(3.15 \text{ V} \le \text{V}_{\text{CC}} \le 3.45 \text{ V}, -40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}, \text{ except as specified. Nominal values are at } \text{V}_{\text{CC}} = 3.3 \text{ V}, \text{T}_{\text{A}} = 25^{\circ}\text{C})$ 

			MIN	NOM	MAX	UNIT
SYNC, SYSRefRe	eq, RampClk, and RampDIR Pins				·	
tonnun	Setup time for pin relative to	SYNC pin	2.5			~~
t <sub>SETUP</sub>	OSCin rising edge	SysRefReq pin	2.5		ns	ns
t <sub>HOLD</sub>	Hold time for SYNC pin	SYNC pin	2			~~
	relative to OSCin rising edge	SysRefReq pin	2			ns
DIGITAL INTERF	ACE WRITE SPECIFICATIONS				·	
f <sub>SPI</sub> Write	SPI write speed	t <sub>CWL</sub> + t <sub>CWH</sub> > 13.333 ns			75	MHz
t <sub>CE</sub>	Clock to enable low time		5			ns
t <sub>DCS</sub>	Data to clock setup time		2			ns
t <sub>CDH</sub>	Clock to data hold time		2			ns
t <sub>CWH</sub>	Clock pulse width high	See Figure 1	5			ns
t <sub>CWL</sub>	Clock pulse width low Enable to clock setup time		5			ns
t <sub>ECS</sub>			5			ns
t <sub>EWH</sub>	Enable pulse width high		2			ns



## **Timing Requirements (continued)**

			MIN	NOM MAX	UNIT
DIGITAL INTERFAC	E READBACK SPECIFICATIONS				
f <sub>SPI</sub> Readback	SPI readback speed			50	MHz
t <sub>CE</sub>	Clock to enable low time		10		ns
t <sub>DCS</sub>	Data to clock setup time		2		ns
t <sub>CDH</sub>	Clock to data hold time		2		ns
t <sub>CR</sub>	Clock falling edge to available readback data wait time.	See Figure 2	0	10	ns
t <sub>CWH</sub>	Clock pulse width high		10		ns
t <sub>CWL</sub>	Clock pulse width low		10		ns
t <sub>ECS</sub>	Enable to clock setup time		10		ns
t <sub>EWH</sub>	Enable pulse width high		10		ns

Enable to clock scap time Enable pulse width high SCK SDI SCK R/W A6 A5 - A1 A0 D15 D14 - D2 D1 D0 Cont C

Figure 1. Serial Data Input Timing Diagram

There are several other considerations for writing on the SPI:

• The R/W bit must be set to 0.

CSB

- The data on SDI pin is clocked into a shift register on each rising edge on the SCK pin.
- The CSB must be held low for data to be clocked. Device will ignore clock pulses if CSB is held high.
- When SCK and SDI lines are shared between devices, TI recommends to hold the CSB line high on the device that is not to be clocked.
- Note that t<sub>CE</sub> is only a valid spec if CPOL (Clock Polarity) = 0 and CPHA (Clock Phase) = 0 is used for SPI protocol. For SPI mode (CPOL = 1 and CPHA = 1), the minimum distance required between the last rising edge of clock and the rising edge of CSB is t<sub>CE</sub> + clock\_period/2.





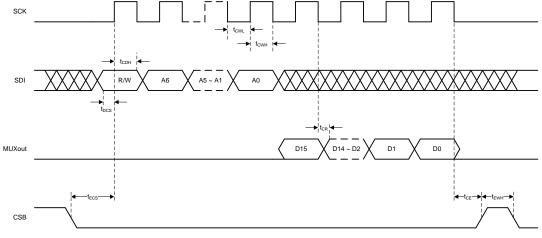


Figure 2. Serial Data Readback Timing Diagram

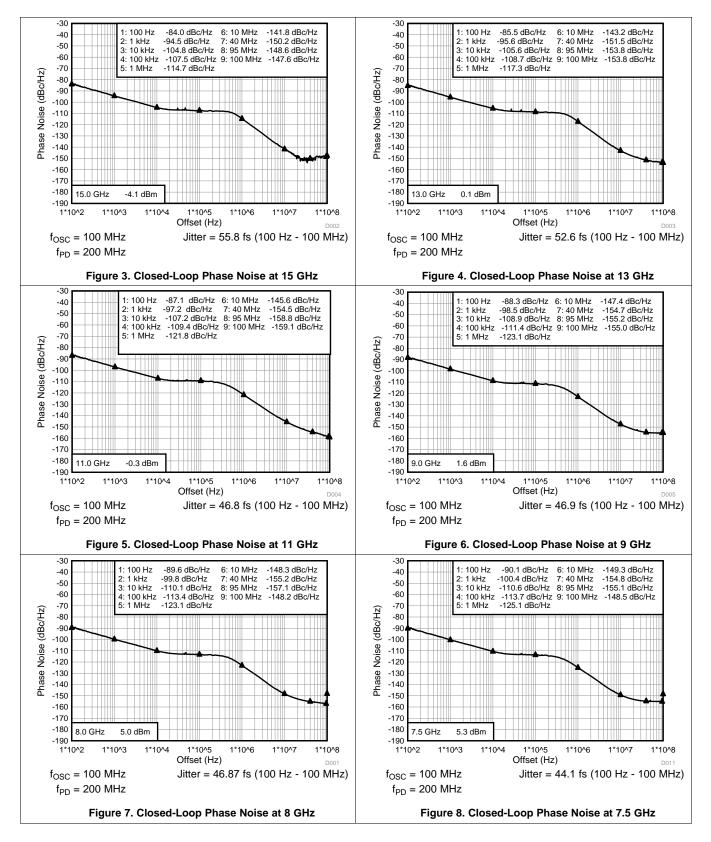
There are several other considerations for SPI readback:

- The R/W bit must be set to 1.
- The MUXout pin will always be low for the address portion of the transaction.
- The data on MUXout is clocked out at t<sub>CR</sub> after the falling edge of SCK. In other words, the readback data will be available at the MUXout pin t<sub>CR</sub> after the clock falling edge.
- The data portion of the transition on the SDI line is always ignored.

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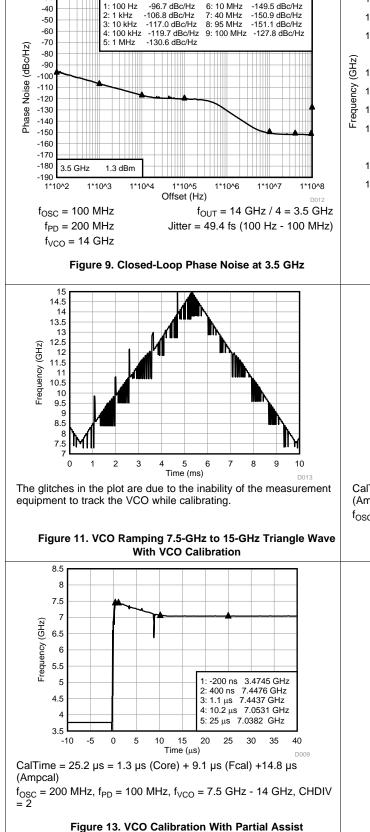
# 6.7 Typical Characteristics





-30

## **Typical Characteristics (continued)**



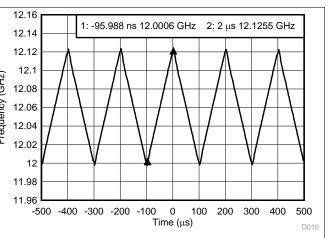
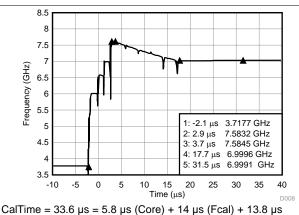


Figure 10. VCO Ramping 12-GHz to 12.125-GHz Calibration Free



(Ampcal)  $(4 - 33.6 \mu s = 5.8 \mu s (Core) + 14 \mu s (Pcar) + 13.8 \mu s$ 

#### Figure 12. VCO Unassisted Calibration

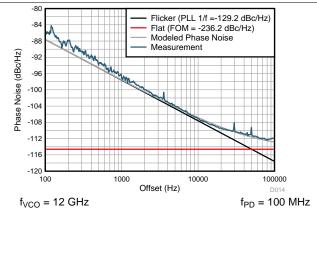


Figure 14. Calculation of PLL Noise Metrics

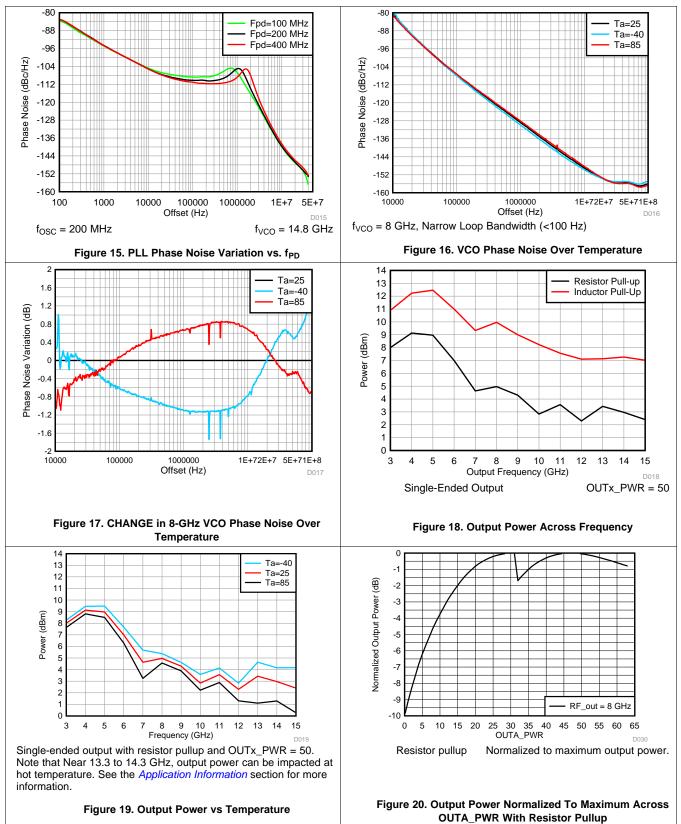
 $f_{OSC}$  = 200 MHz,  $f_{PD}$  = 100 MHz,  $f_{VCO}$  = 7.5 - 14 GHz, CHDIV = 2

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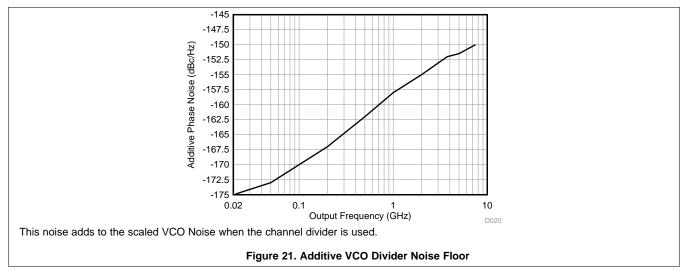
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## **Typical Characteristics (continued)**





# **Typical Characteristics (continued)**





## 7 Detailed Description

## 7.1 Overview

The LMX2594 is a high-performance, wideband frequency synthesizer with integrated VCO and output divider. The VCO operates from 7.5 GHz to 15 GHz, and this can be combined with the output divider to produce any frequency in the range of 10 MHz to 15 GHz. Within the input path, there are two dividers and a multiplier for flexible frequency planning. The multiplier also allows the reduction of spurs by moving the frequencies away from the integer boundary.

The PLL is fractional-N PLL with a programmable delta-sigma modulator up to 4<sup>th</sup> order. The fractional denominator is a programmable 32-bit long, which can easily provide fine frequency steps below 1-Hz resolution, or be used to do exact fractions like 1/3, 7/1000, and many others. The phase frequency detector goes up to 300 MHz in fractional mode or 400 MHz in integer mode, although minimum N-divider values must also be taken into account.

For applications where deterministic or adjustable phase is desired, the SYNC pin can be used to get the phase relationship between the OSCin and RFout pins deterministic. When this is done, the phase can be adjusted in very fine steps of the VCO period divided by the fractional denominator.

The ultra-fast VCO calibration is designed for applications where the frequency must be swept or abruptly changed. The frequency can be manually programmed, or the device can be set up to do ramps and chirps.

The JESD204B support includes using the RFoutB output to create a differential SYSREF output that can be either a single pulse or a series of pulses that occur at a programmable distance away from the rising edges of the output signal.

The LMX2594 device requires only a single 3.3-V power supply. The internal power supplies are provided by integrated LDOs, eliminating the need for high-performance external LDOs.

The digital logic for the SPI interface and is compatible with voltage levels from 1.8 V to 3.3 V.

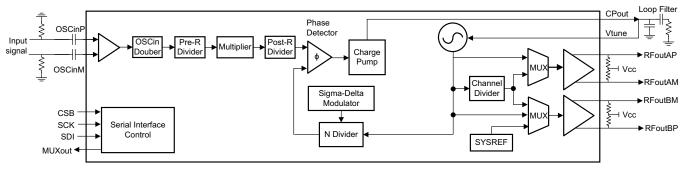
Table 1 shows the range of several of the dividers, multipliers, and fractional settings.

PARAMETER	MIN	MAX	COMMENTS
Outputs enabled	0	2	
OSCin doubler	0 (1X)	1 (2X)	The low noise doubler can be used to increase the phase detector frequency to improve phase noise and avoid spurs. This is in reference to the OSC_2X bit.
Pre-R divider	1 (bypass)	128	Only use the Pre-R divider if the multiplier is used and the input frequency is too high for the multiplier.
Multiplier	3	7	This is in reference to the MULT word.
Post-R divider	1 (bypass)	255	The maximum input frequency for the Post-R divider is 250 MHz. Use the Pre-R divider if necessary.
N divider	≥ 28	524287	The minimum divide depends on modulator order and VCO frequency. See <i>N-Divider and Fractional Circuitry</i> for more details.
Fractional numerator/ denominator	1 (Integer mode)	2 <sup>32</sup> – 1 = 4294967295	The fractional denominator is programmable and can assume any value between 1 and 2 <sup>32</sup> –1; it is not a fixed denominator.
Fractional order (MASH_ORDER)	0	4	Order 0 is integer mode and the order can be programmed
Channel divider	1 (bypass)	768	This is the series of several dividers. Also, be aware that above 10 GHz, the maximum allowable channel divider value is 6.
Output frequency	10 MHz	10 MHz15 GHzThis is implied by the minimum VCO frequency by the maximum channel divider value.	

#### Table 1. Range of Dividers, Multipliers, and Fractional Settings



#### 7.2 Functional Block Diagram



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## 7.3 Feature Description

#### 7.3.1 Reference Oscillator Input

The OSCin pins are used as a frequency reference input to the device. The input is high impedance and requires AC-coupling caps at the pin. A CMOS clock or XO can drive the single-ended OSCin pins. Differential clock input is also supported, making it easier to interface with high-performance system clock devices such as TI's LMK series clock devices. As the OSCin signal is used as a clock for the VCO calibration, a proper reference signal must be applied at the OSCin pin at the time of programming FCAL\_EN.

#### 7.3.2 Reference Path

The reference path consists of an OSCin doubler (OSC\_2X), Pre-R divider, multiplier (MULT) and a Post-R divider.

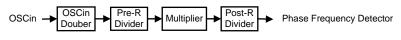


Figure 22. Reference Path Diagram

The OSCin doubler (OSC\_2X) can double up low OSCin frequencies. Pre-R (PLL\_R\_PRE) and Post-R (PLL\_R) dividers both divide frequency down while the multiplier (MULT) multiplies frequency up. The purposes of adding a multiplier is to reduce integer boundary spurs or to increase the phase detector frequency. Use Equation 1 to calculate the phase detector frequency,  $f_{PD}$ :

 $f_{PD} = f_{OSC} \times OSC_{2X} \times MULT / (PLL_R_PRE \times PLL_R)$ 

(1)

- In the OSCin doubler or input multiplier is used, the OSCin signal should have a 50% duty cycle as both the rising and falling edges are used.
- If neither the OSCin doubler nor the input multiplier are used, only rising edges of the OSCin signal are used and duty cycle is not critical.
- The input multiplier and OSCin doubler should not both be used at the same time.



#### Feature Description (continued)

#### 7.3.2.1 OSCin Doubler (OSC\_2X)

The OSCin doubler allows one to double the input reference frequency up to 400 MHz. This doubler adds minimal noise and is useful for raising the phase detector frequency for better phase noise and also to avoid spurs. When the phase-detector frequency is increased, the flat portion of the PLL phase noise improves.

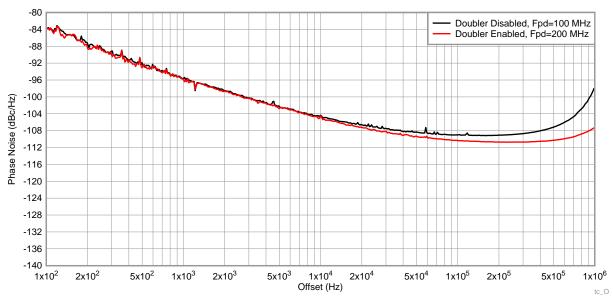


Figure 23. Benefit of Using the OSC\_2X Doubler at 14 GHz

#### 7.3.2.2 Pre-R Divider (PLL\_R\_PRE)

The Pre-R divider is useful for reducing the input frequency so that the programmable multiplier (MULT) can be used to help meet the maximum 250-MHz input frequency limitation to the PLL-R divider. Otherwise, it does not have to be used.

#### 7.3.2.3 Programmable Multiplier (MULT)

The MULT is useful for shifting the phase-detector frequency to avoid integer boundary spurs. The multiplier allows a multiplication of 3, 4, 5, 6, or 7. Be aware that unlike the doubler, the programmable multiplier degrades the PLL figure of merit. This only would matter, however, for a clean reference and if the loop bandwidth was wide.

#### 7.3.2.4 Post-R Divider (PLL\_R)

The Post-R divider can be used to further divide down the frequency to the phase detector frequency. When it is used ( $PLL_R > 1$ ), the input frequency to this divider is limited to 250 MHz.

#### 7.3.2.5 State Machine Clock

The state machine clock is a divided down version of the OSCin signal that is used internally in the device. This divide value is 1, 2, 4, or 8, and is determined by CAL\_CLK\_DIV programming word (described in the *Programming* section). This state machine clock impacts various features like the lock detect delay, VCO calibration, and ramping. The state machine clock is calculated as  $f_{smclk} = f_{OSC} / 2^{CAL_CLK_DIV}$ .

#### 7.3.3 PLL Phase Detector and Charge Pump

The phase detector compares the outputs of the Post-R divider and N-divider, and generates a correction current corresponding to the phase error until the two signals are aligned in-phase. This charge-pump current is software programmable to many different levels, allowing modification of the closed-loop bandwidth of the PLL. See the *Application Information* section for more information.



#### Feature Description (continued)

#### 7.3.4 N-Divider and Fractional Circuitry

The N-divider includes fractional compensation and can achieve any fractional denominator from 1 to  $(2^{32} - 1)$ . The integer portion of N is the whole part of the N-divider value, and the fractional portion, N<sub>frac</sub> = NUM / DEN, is the remaining fraction. In general, the total N-divider value is determined by N + NUM / DEN. The N, NUM and DEN are software programmable. The higher the denominator, the finer the resolution step of the output. For example, even when using f<sub>PD</sub> = 200 MHz, the output can increment in steps of 200 MHz /  $(2^{32} - 1) = 0.047$  Hz. Equation 2 shows the relationship between the phase detector and VCO frequencies. Note that in SYNC mode, there is an extra divider that is not shown in Equation 2.

$$f_{VCO} = f_{pd} \times \left(N + \frac{NUM}{DEN}\right)$$
(2)

The sigma-delta modulator that controls this fractional division is also programmable from integer mode to fourth order. To make the fractional spurs consistent, the modulator is reset any time that the R0 register is programmed.

The N-divider has minimum value restrictions based on the modulator order and VCO frequency. Furthermore, the PFD\_DLY\_SEL bit must be programmed in accordance to the Table 2.

MASH_ORDER	f <sub>VCO</sub> (MHz)	MINIMUM N	PFD_DLY_SEL
0	≤ 12500	28	1
	> 12500	32	2
1	≤ 10000	28	1
	10000-12500	32	2
	>12250	36	3
2	≤ 10000	32	2
	>10000	36	3
3	≤ 10000	36	3
	>10000	40	4
4	≤ 10000	44	5
	>10000	48	6

#### **Table 2. Minimum N-Divider Restrictions**

## 7.3.5 MUXout Pin

The MUXout pin can be used to readback programmable states of the device or for lock detect.

MUXOUT_SEL	FUNCTION
0	Readback
1	Lock Detect

#### 7.3.5.1 Lock Detect

The MUXout pin can be configured for lock detect done in by reading back the rb\_LD\_VTUNE field or using the pin as shown in the Table 4.

FIELD	PROGRAMMING	DESCRIPTION
LD_TYPE	0 = VCO Calibration Status 1 = Indirect Vtune	Select Lock Detect Type.
LD_DLY	0 to 65535	Only valid for Vtune lock detect. This is a delay in state machine cycles.
OUT_MUTE	0 = Disabled 1 = Enabled	Turns off outputs when lock detect is low.

#### Table 4. Configuring the MUXout Pin for Lock Detect



(3)

VCO calibration status lock detect works by indicating a low signal on the MUXout pin whenever the VCO is calibrating or the LD\_DLY counter is running. The delay from the LD\_DLY is added to the true VCO calibration time ( $t_{VCOCAL}$ ), so it can be used to account for the analog lock time of the PLL.

Indirect Vtune lock detect is based on internally generated voltage that is related to (but not the same as) the Vtune voltage of the charge pump. It indicates a high signal on MUXout pin or reads back state 2 of rb\_LD\_VTUNE when the device is locked.

#### 7.3.5.2 Readback

The MUXout pin can be configured to read back useful information from the device. Common uses for readback are:

- 1. Read back registers to ensure that they have been programmed to the correct value.
- 2. Read back the lock detect status to determine if the PLL is in lock.
- 3. Read back VCO calibration information so that it can be used to improve the lock time.
- 4. Read back information to help troubleshoot.

#### 7.3.6 VCO (Voltage-Controlled Oscillator)

The LMX2594 includes a fully integrated VCO. The VCO takes the voltage from the loop filter and converts this into a frequency. The VCO frequency is related to the other frequencies is shown in Equation 3:

 $f_{VCO} = f_{PD} \times N$  divider

#### 7.3.6.1 VCO Calibration

To reduce the VCO tuning gain and therefore improve the VCO phase-noise performance, the VCO frequency range is divided into several different frequency bands. The entire range, 7.5 to 15 GHz, covers an octave that allows the divider to take care of frequencies below the lower bound. This creates the need for frequency calibration to determine the correct frequency band given a desired output frequency. The frequency calibration routine is activated any time that the R0 register is programmed with the FCAL\_EN = 1. It is important that a valid OSCin signal must present before VCO calibration begins.

The VCO also has an internal amplitude calibration algorithm to optimize the phase noise which is also activated any time the R0 register is programmed.

The optimum internal settings for this are temperature dependent. If the temperature is allowed to drift too much without being recalibrated, some minor phase noise degradation could result. The maximum allowable drift for continuous lock,  $\Delta T_{CL}$ , is stated in the electrical specifications. For this device, a number of 125°C means the device never loses lock if the device is operated under the *Recommended Operating Conditions*.



The LMX2594 allows the user to assist the VCO calibration. In general, there are three kinds of assistance, as shown in Table 5:

Table 5. Assisting the VCO Calibration Speed				
ASSISTANCE LEVEL	DESCRIPTION	PROGRAMMABLE SETTINGS		
No assist	User does nothing to improve VCO calibration speed, but the user-specified VCO_SEL, VCO_DACISET_STRT and VCO_CAPCTRL_STRT values do affect the starting point of VCO calibration. For oscillation to start up properly and for VCO to calibrate correctly, TI recommends setting VCO_SEL = 7, VCO_DACISET_STRT = 300 and VCO_CAPCTRL_STRT = 183 for all frequencies except 11.9 GHz ~ 12.1 GHz. For frequencies within 11.9 ~ 12.1 GHz, user must use VCO_SEL = 4 for proper VCO calibration.	QUICK_RECAL_EN=0 VCO_SEL_FORCE=0 VCO_DACISET_FORCE=0 VCO_CAPCTRL_FORCE=0		
Partial assist	Upon every frequency change, before the FCAL_EN bit is checked, the user provides the initial starting point for the VCO core (VCO_SEL), band (VCO_CAPCTRL_STRT), and amplitude (VCO_DACISET_STRT) based on Table 6.	QUICK_RECAL_EN=0 VCO_SEL_FORCE=0 VCO_DACISET_FORCE=0 VCO_CAPCTRL_FORCE=0		
Close Frequency Assist	Upon initialization of the device, user enables QUICK_RECAL_EN bit. The VCO uses the current VCO_CAPCTRL and VCO_DACISET_STRT settings as the initial starting point.	QUICK_RECAL_EN=1 VCO_SEL_FORCE=0 VCO_DACISET_FORCE=0 VCO_CAPCTRL_FORCE=0		
Full assist	The user forces the VCO core (VCO_SEL), amplitude settings (VCO_DACISET), and frequency band (VCO_CAPCTRL) and manually sets the value. If the two frequency points are no more than 5MHz apart and on the same VCO core, the user can set the VCO amplitude and capcode for any frequency between those two points using linear interpolation.	QUICK_RECAL_EN=0 VCO_SEL_FORCE=1 VCO_DACISET_FORCE=1 VCO_CAPCTRL_FORCE=1		

Table 5. Assisting the VCO Calibration Speed

To do the partial assist for the VCO calibration, follow this procedure:

1. Determine the VCO Core

Find a VCO Core that includes the desired VCO frequency. If at the boundary of two cores, choose one based on phase noise or performance.

- 2. Calculate the VCO CapCode as follows:
- $VCO\_CAPCTRL\_STRT = round (C_{CoreMin} (C_{CoreMin} C_{CoreMax}) \times (f_{VCO} f_{CoreMin}) / (f_{CoreMax} f_{CoreMin}))$ 3. Get the VCO amplitude setting from Table 6.

VCO\_DACISET\_STRT = round ( $A_{CoreMin} + (A_{CoreMax} - A_{CoreMin}) \times (f_{VCO} - f_{CoreMin})/(f_{CoreMax} - f_{CoreMin})$ )

VCO CORE	f <sub>CoreMin</sub>	f <sub>CoreMax</sub>	C <sub>CoreMin</sub>	C <sub>CoreMax</sub>	A <sub>CoreMin</sub>	A <sub>CoreMax</sub>
VCO1	7500	8600	164	12	299	240
VCO2	8600	9800	165	16	356	247
VCO3	9800	10800	158	19	324	224
VCO4	10800	12000	140	0	383	244
VCO5	12000	12900	183	36	205	146
VCO6	12900	13900	155	6	242	163
VCO7	13900	15000	175	19	323	244

#### Table 6. VCO Core Ranges

#### NOTE

In the range of 11900 MHz to 12100 MHz, VCO assistance cannot be used, and the settings must be: VCO\_SEL = 4, VCO\_DACISET\_STRT = 300, and VCO\_CAPCTRL\_STRT = 1. Outside this range, in the partial assist for the VCO calibration, the VCO calibration runs. This means that if the settings are incorrect, the VCO still locks with the correct settings. The only consequence is that the calibration time might be a little longer. The closer the calibration settings are to the true final settings, the faster the VCO calibration will be.

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(4)

#### 7.3.6.2 Determining the VCO Gain

The VCO gain varies between the seven cores and is the lowest at the lowest end of the band and highest at the highest end of each band. For a more accurate estimation, use Table 7:

CORE	f1	f2	Kvco1	Kvco2
VCO1	7500	8600	73	114
VCO2	8600	9800	61	121
VCO3	9800	10800	98	132
VCO4	10800	12000	106	141
VCO5	12000	12900	170	215
VCO6	12900	13900	172	218
VCO7	13900	15000	182	239

#### Table 7. VCO Gain

Based on Table 7, Equation 4 can estimate the VCO gain for an arbitrary VCO frequency of f<sub>VCO</sub>:

 $Kvco = Kvco1 + (Kvco2 - Kvco1) \times (f_{VCO} - f1) / (f2 - f1)$ 

#### 7.3.7 Channel Divider

To go below the VCO lower bound of 7.5 GHz, the channel divider can be used. The channel divider consists of four segments, and the total division value is equal to the multiplication of them. Therefore, not all values are valid.

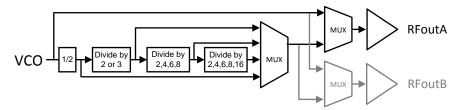


Figure 24. Channel Divider

When the channel divider is used, there are limitations on the values. Table 8 shows how these values are implemented and which segments are used.



EQUIVALENT DIVISION VALUE	FREQUENCY LIMITATION	OutMin (MHz)	OutMax (MHz)	CHDIV[4:0]	SEG0	SEG1	SEG2	SEG3
2		3750	7500	0	2	1	1	1
4	None	1875	3750	1	2	2	1	1
6		1250	2500	2	2	3	1	1
8		937.5	1437.5	3	2	2	2	1
12		625	958.333	4	2	3	2	1
16		468.75	718.75	5	2	2	4	1
24		312.5	479.167	6	2	2	6	1
32		234.375	359.375	7	2	2	8	1
48		156.25	239.583	8	2	3	8	1
64		117.1875	179.6875	9	2	2	8	2
72	f <sub>VCO</sub> ≤ 11.5 GHz	104.167	159.722	10	2	3	6	2
96		78.125	119.792	11	2	3	8	2
128		58.594	89.844	12	2	2	8	4
192		39.0625	59.896	13	2	2	8	6
256		29.297	44.922	14	2	2	8	8
384		19.531	29.948	15	2	3	8	8
512	-	14.648	22.461	16	2	2	8	16
768		9.766	14.974	17	2	3	8	16
Invalid	n/a	n/a	n/a	18-31	n/a	n/a	n/a	n/a

#### Table 8. Channel Divider Segments

The channel divider is powered up whenever an output (OUTx\_MUX) is selected to the channel divider or SysRef, regardless of whether it is powered down or not. When an output is not used, TI recommends selecting the VCO output to ensure that the channel divider is not unnecessarily powered up.

#### Table 9. Channel Divider

OUTA MUX	OUTB MUX	CHANNEL DIVIDER	
Channel Divider	Х	Powered up	
X	Channel Divider or SYSREF	Powered up	
All Othe	Powered down		

#### 7.3.8 Output Buffer

The RF output buffer type is open collector and requires an external pullup to Vcc. This component may be a 50- $\Omega$  resistor to target 50- $\Omega$  output impedance match, or an inductor for higher output power at the expense of the output impedance being far from 50  $\Omega$ . If inductor is used, it is recommended to follow with resistive pad for better impedance matching. The current to the output buffer increases for states 0 to 31 and then again from states 48 to 63. States 32 to 47 are redundant and mimic states 16 to 31. If using a resistor, limit the OUTx\_PWR setting to 50. Higher settings may actually reduce power due to the voltage drop across the resistor.

#### Table 10. OUTx\_PWR Recommendations for Resistor Pullup

	RECOMMENDATION			
<sup>f</sup> ouт	HIGHEST POWER	LOWEST NOISE FLOOR	COMMENTS	
10 MHz ≤ f <sub>OUT</sub> < 13.3 GHz	OUTx_PWR = 50	OUTx_PWR = 50	-	
13.3 GHz ≤ f <sub>OUT</sub> ≤ 14.3 GHz	OUTx_PWR = 15	OUTx_PWR = 15	TI recommends to set $OUTx_PWR \le 15$ to avoid the power drop at hot temperature.	
14.3 GHz < f <sub>OUT</sub> ≤ 15 GHz	OUTx_PWR = 31	OUTx_PWR = 20	-	



#### 7.3.9 Power-Down Modes

The LMX2594 can be powered up and down using the CE pin or the POWERDOWN bit. When the device comes out of the powered down state, either by resuming the POWERDOWN bit to zero or by pulling back CE pin HIGH, register R0 must be programmed with FCAL\_EN high again to re-calibrate the device.

#### 7.3.10 Phase Synchronization

#### 7.3.10.1 General Concept

The SYNC pin allows one to synchronize the LMX2594 such that the delay from the rising edge of the OSCin signal to the output signal is deterministic. Initially, the devices are locked to the input, but are not synchronized. The user sends a synchronization pulse that is reclocked to the next rising edge of the OSCin pulse. After a given time,  $t_1$ , the phase relationship from OSCin to  $f_{OUT}$  will be deterministic. This time is dominated by the sum of the VCO calibration time, the analog setting time of the PLL loop, and the MASH\_RST\_CNT if used in fractional mode.

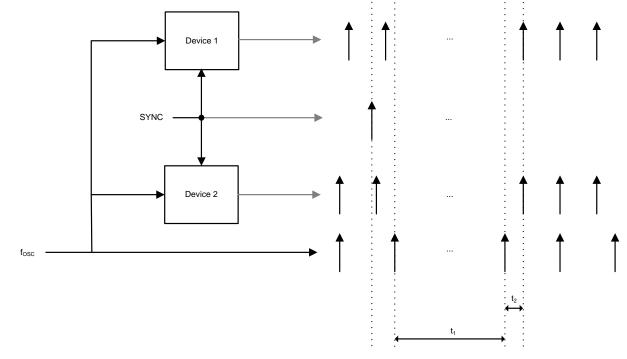


Figure 25. Devices Are Now Synchronized to OSCin Signal

When the SYNC feature is enabled, part of the channel divide may be included in the feedback path. This will be referred to as *IncludedDivide* 

Table 11. IncludedDivide With	VCO PHASE SYNC = 1
-------------------------------	--------------------

OUTx_MUX	CHANNEL DIVIDER	INCLUDEDDIVIDE
OUTA_MUX = OUTB_MUX = 1 ("VCO")	Don't Care	1
	Divisible by 3, but NOT 24 or 192	$SEG0 \times SEG1 = 6$
All Other Valid Conditions	All other values	$SEG0 \times SEG1 = 4$



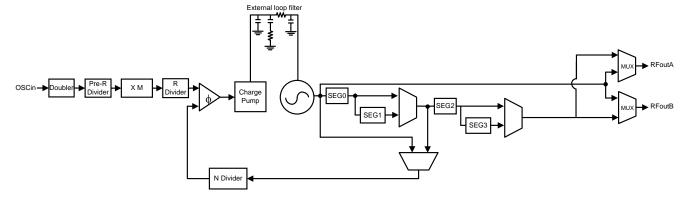


Figure 26. Phase SYNC Diagram

#### 7.3.10.2 Categories of Applications for SYNC

The requirements for SYNC depend on certain setup conditions. In cases that the SYNC is not timing critical, it can be done through software by toggling the VCO\_PHASE\_SYNC bit from 0 to 1. When it is timing critical, then it must be done through the pin and the setup and hold times for the OSCin pin are critical. Figure 27 gives the different categories.

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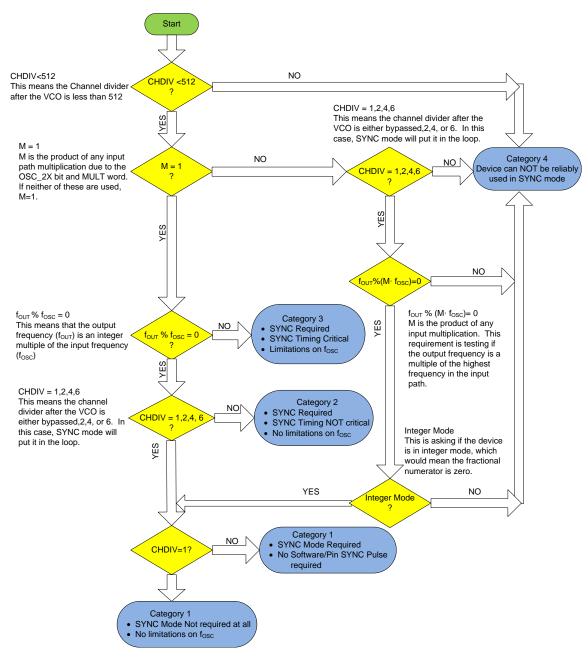


Figure 27. Determining the SYNC Category



#### 7.3.10.3 Procedure for Using SYNC

This procedure must be used to put the device in SYNC mode.

- 1. Use the flowchart to determine the SYNC category.
- 2. Make determinations for OSCin and using SYNC based on the category.
  - 1. If Category 4, SYNC cannot be performed in this setup.
  - 2. If category 3, ensure that the maximum  $f_{OSC}$  frequency for SYNC is not violated and there are hardware accommodations to use the SYNC pin.
- 3. Determine the value of IncludedDivide:
  - 1. If OUTA\_MUX is not channel divider and OUTB\_MUX is not channel divider or SysRef, then IncludedDivide = 1.
  - 2. Otherwise, IncludedDivide =  $2 \times SEG1$ . In the case that the channel divider is 2, then IncludedDivide=4.
- 4. If not done already, divide the N-divider and fractional values by IncludedDivide to account for the IncludedDivide.
- 5. Program the device with the VCO\_PHASE\_SYNC = 1. Note that this does not count as applying a SYNC to device (for category 2).
- 6. Apply the SYNC, if required:
  - 1. If category 2, VCO\_PHASE\_SYNC can be toggled from 0 to 1. Alternatively, a rising edge can be sent to the SYNC pin and the timing of this is not critical.
  - If category 3, the SYNC pin must be used, and the timing must be away from the rising edge of the OSCin signal. Toggling the SYNC pin runs VCO calibration when FCAL\_EN = 1. If FCAL\_EN = 0 then SYNC pin does not function.

#### 7.3.10.4 SYNC Input Pin

The SYNC input pin can be driven either in CMOS or LVDS mode. However, if not using SYNC mode (VCO\_PHASE\_SYNC = 0), then the INPIN\_IGNORE bit must be set to one, otherwise it causes issues with lock detect. If the pin is desired for to be used and VCO\_PHASE\_SYNC = 1, then set INPIN\_IGNORE = 0. LVDS or CMOS mode may be used. LVDS works to 250 mVPP, but is not ensured in production.

#### 7.3.11 Phase Adjust

The MASH\_SEED word can use the sigma-delta modulator to shift output signal phase with respect to the input reference. If a SYNC pulse is sent (software or pin) or the MASH is reset with MASH\_RST\_N, then this phase shift is from the initial phase of zero. If the MASH\_SEED word is written to, then this phase is added. Use Equation 5 to calculate the phase shift.

Phase shift in degrees = 360 × (MASH\_SEED / PLL\_DEN) × (IncludedDivide / CHDIV)

(5)

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Example:

Mash seed = 1

Denominator = 12

Channel divider = 16

Phase shift (VCO\_PHASE\_SYNC = 0) =  $360 \times (1/12) \times (1/16) = 1.875$  degrees

Phase Shift (VCO\_PHASE\_SYNC = 1) =  $360 \times (1/12) \times (4/16) = 7.5$  degrees

There are several considerations with phase shift with MASH\_SEED:

- Phase shift can be done with a FRAC\_NUM = 0, but MASH\_ORDER must be greater than zero. For MASH\_ORDER = 1, the phase shifting only occurs when MASH\_SEED is a multiple of PLL\_DEN.
- For the phase adjust, the condition PLL\_DEN > PLL\_NUM + MASH\_SEED must be satisfied.
- When MASH\_SEED and Phase SYNC are used together with IncludedDivide > 1, additional constraints may be necessary to produce a monotonic relationship between MASH\_SEED and the phase shift, especially when the VCO frequency is below 10 GHz. These constraints are application specific, but some general guidelines are to reduce modulator order and increase the N divider. One possible guideline is for PLL\_N ≥ 45 (2nd order modulator), PLL\_N ≥ 49 (3rd Order modulator), PLL\_N ≥ 54 (4th Order Modulator).

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#### 7.3.12 Fine Adjustments for Phase Adjust and Phase SYNC

Phase SYNC refers to the process of getting the same phase relationship for every power-up cycle and each time assuming that a given programming procedure is followed. However, there are some adjustments that can be made to get the most accurate results. As for the consistency of the phase SYNC, the only source of variation could be if the VCO calibration chooses a different VCO core and capacitor, which can introduce a bimodal distribution with about 10 ps of variation. If this 10 ps is not desirable, then it can be eliminated by reading back the VCO core, capcode, and DACISET values and forcing these values to ensure the same calibration settings every time. The delay through the device varies from part to part and can be on the order of 60 ps. This part to part variation can be calibrated out with the MASH\_SEED. The variation in delay through the device also changes on the order of +2.5 ps/°C, but devices on the same board likely have similar temperatures, so this will somewhat track. In summary, the device can be made to have consistent delay through the part and there are means to adjust out any remaining errors with the MASH\_SEED. This tends only to be an issue at higher output frequencies when the period is shorter.

#### 7.3.13 Ramping Function

The LMX2594 supports the ability to make ramping waveforms using manual mode or automatic mode. In manual mode, the user defines a step and uses the RampClk and RampDir pins to create the ramp. In automatic mode, the user sets up the ramp with up to two linear segments in advance and the device automatically creates this ramp. Table 12 fields apply in both automatic mode and manual pin mode.

FIELD	PROGRAMMING	DESCRIPTION			
	GENERAL COMMANDS				
RAMP_EN	0 = Disabled 1 = Enabled	RAMP_EN must be 1 for any ramping functions to work.			
RAMP_MANUAL	0 = Automatic ramping mode 1 = Manual pin ramping mode	In automatic ramping mode, the ramping is automatic and the clock is based on the phase detector. In manual pin ramping mode, the clock is based on rising edges on the RampClk pin.			
RAMPx_INC	0 to $2^{30} - 1$	This is the amount the fractional numerator is increased for each phase detector cycle in the ramp.			
RAMPx_DLY	0 to 65535	This is the length of the ramp in phase detector cycles.			
	DEALING WITH VCO CA	LIBRATION			
RAMP_THRESH	0 to $\pm 2^{33} - 1$	Whenever the fractional numerator changes this much (either positive or negative) because the VCO was last calibrated, the VCO is forced to recalibrate.			
RAMP_TRIG_CAL	0 = Disabled 1 = Enabled	When enabled, the VCO is forced to recalibrate at the beginning each ramp.			
PLL_DEN	4294967295	In ramping mode, the denominator must be fixed to this forced value of $2^{32} - 1$ . However, the effective denominator in ramping mode is $2^{24}$ .			
LD_DLY	0	This must be zero to avoid interfering with calibration.			
	RAMP LIMIT	S			
RAMP_LIMIT_LOW RAMP_LIMIT_HIGH	0 to $\pm 2^{33} - 1$	2's complement of the total value of the ramp low and high limits can never go beyond. If this value is exceeded, then the frequency is limited.			

#### Table 12. Ramping Field Descriptions



#### Table 13. General Restrictions for Ramping

RULE	RESTRICTION	EXPLANATION
Phase Detector Frequency	f <sub>OSC</sub> /2 <sup>CAL_CLK_DIV</sup> ≤ f <sub>PD</sub> ≤ 125 MHz	<b>Minimum Phase Detector Frequency when Ramping</b> The phase detector frequency cannot be less than the state machine clock frequency, which is calculated from expression on the left-hand side of the inequality. This is satisfied provided there is no division in the input path. However, if the PLL R-divider is used, it is necessary to adjust CAL_CLK_DIV to adjust the state machine clock frequency. This also implies a maximum R divide of 8 this is the maximum value of 2 <sup>CAL_CLK_DIV</sup> .
		Maximum Phase Detector Frequency TI recommends to set the phase-detector frequency ≤ 125 MHz because, if the phase detector frequency is too high, it can lead to distortion in the ramp. Higher phase-detector frequency may be possible, but this distortion is application specific.

#### 7.3.13.1 Manual Pin Ramping

Manual pin ramping is enabled by setting RAMP\_EN = 1 and RAMP\_MANUAL = 1. The rising edges are applied to the RampClk pin are reclocked to the phase detector frequency. The RampDir pin controls the size of the change. If a rising edge is seen on the RampClk pin while the VCO is calibrating, then this rising edge is ignored. The frequency for the RampClk must be limited to a frequency of 250 kHz or less, and the rising edge of the RampDir signal must be targeted away from the rising edges of the RampCLK pin.

#### Table 14. RAMP\_INC

RampDir PIN	STEP SIZE
Low	Add RAMP0_INC
High	Add RAMP1_INC

#### 7.3.13.1.1 Manual Pin Ramping Example

In this ramping example, assume that we want to use the pins for UP/Down control of the ramp for 10-MHz steps and the phase detector is 100 MHz.

FIELD	PROGRAMMING	DESCRIPTION
RAMP_EN	1 = Enabled	
RAMP_MANUAL	1 = Manual pin ramping mode	
RAMP0_INC	1677722	(10 MHz )/ (100 MHz) × 16777216 = 1677722 2's complement = 1677722
RAMP1_INC	1072064102	$(-10 \text{ MHz})/(100 \text{ MHz}) \times 16777216 = -1677722$ 2's complement = $2^{30} - 1677722 = 1072064102$
RAMP_TRIG_CAL	1	Recalibrate at every clock cycle

## Table 15. Step Ramping Example

Output Frequency

RampClk/Trig1 Pin

RampDir/Trig2 Pin

:

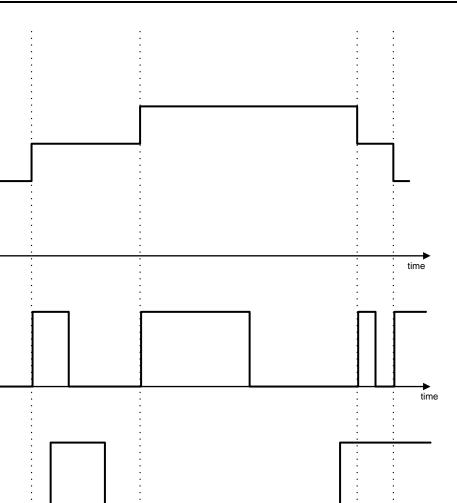


Figure 28. Step Ramping Example

time



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#### 7.3.13.2 Automatic Ramping

Automatic ramping is enabled when RAMP\_EN = 1 and RAMP\_MANUAL = 0. The action of programming FCAL = 1 starts the ramping. In this mode, there are two ramps that one can use to set the length and frequency change. In addition to this, there are ramp limits that can be used to create more complicated waveforms.

Automatic ramping can really be divided into two classes depending on if the VCO must calibrate in the middle of the ramping waveform or not. If the VCO can go the entire range without calibrating, this is calibration-free ramping, which is shown in *Typical Characteristics*. Note that this range is less at hot temperatures and for lower frequency VCOs. This range is not ensured, so margin must be built into the design.

For waveforms that are NOT calibration free, the slew rate of the ramp must be kept less than 250 kHz/µs. Also, for all automatic ramping waveforms, be aware that there is a very small phase disturbance as the VCO crosses over the integer boundary, so one might consider using the input multiplier to avoid these or timing the VCO calibrations at integer boundaries.

PROGRAMMING	DESCRIPTION
0 = One clock cycle 1 = Two clock cycles	Normally, the ramp clock is equal to the phase detector frequency. When this feature is enabled, it reduces the ramp clock by a factor of 2.
0 to 65535	This is the length of the ramp in clock cycles. Note that the VCO calibration time is added to this time.
0 to $2^{30} - 1$	2's complement of the value for the ramp increment.
0 = RAMP0 1 = RAMP1	Defines which ramp comes after the current ramp.
0 = Timeout counter 1 = Trigger A 2 = Trigger B 3 = Reserved	Determines what triggers the action of the next ramp occurrence.
0 = Disabled 1 = RampClk rising edge 2 = RampDir rising edge 4 = Always triggered 9 = RampClk falling edge 10 = RampDir falling edge All other States = invalid	This field defines the ramp trigger.
0 = Disabled 1 = Enabled	Enabling this bit causes the ramp to reset to the original value when the ramping started. This is useful for roundoff errors.
0 to 8191	This is the number the ramping pattern repeats and only applies for a terminating ramping pattern.
0 = Ramp Transition 1 = Trigger A 2 = Trigger B 3 = Reserved	This defines what causes the RAMP_COUNT to increment.
	0 = One clock cycle 1 = Two clock cycles 0 to 65535 0 to $2^{30} - 1$ 0 = RAMP0 1 = RAMP1 0 = Timeout counter 1 = Trigger A 2 = Trigger B 3 = Reserved 0 = Disabled 1 = RampClk rising edge 2 = RampDir rising edge 4 = Always triggered 9 = RampClk falling edge 10 = RampDir falling edge 10 = RampDir falling edge 10 = RampDir falling edge 11 = Enabled 1 = Enabled 0 to 8191 0 = Ramp Transition 1 = Trigger A

**Table 16. Automatic Ramping Field Descriptions** 



#### 7.3.13.2.1 Automatic Ramping Example (Triangle Wave)

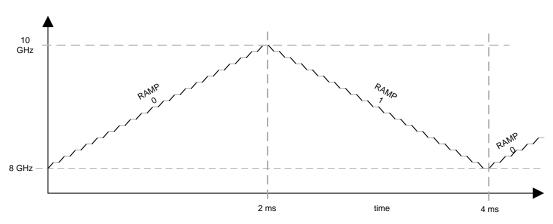
Suppose user wants to generate a sawtooth ramp that goes from 8 to 10 GHz in 2 ms (including calibration breaks) with a phase-detector frequency of 50 MHz. Divide this into segments of 50 MHz where the VCO ramps for 25  $\mu$ s, then calibrates for 25  $\mu$ s, for a total of 50  $\mu$ s. There would therefore be 40 such segments which span over a 2-GHz range and would take 2 ms, including calibration time.

FIELD	PROGRAMMING	DESCRIPTION
RAMP_EN	1 = Enabled	
RAMP_MANUAL	0 = Automatic ramping mode	
RAMP_TRIG_CAL	0 = Disabled	
RAMP_THRESH	16777216 (= 50-MHz ramp_thresh)	50 MHz / 50 MHz × 2 <sup>24</sup> = 16777216
RAMP_DLY	0 = 1 clock cycle	
RAMPx_LEN	50000	1000 μs × 50 MHz = 50000
RAMP0_INC	13422	(2000 MHz) / (50 MHz) × 2 <sup>24</sup> / 50000 = 13422
RAMP1_INC	1073728402	$(-2000 \text{ MHz}) / (50 \text{ MHz}) \times 2^{24} / 50000 = -13422$ 2's complement = $2^{30} - 13422 = 1073728402$
RAMP0_NEXT	1 = RAMP1	
RAMP1_NEXT	0 = RAMP0	
RAMPx_NEXT_TRIG	0 = Timeout counter	
RAMP_TRIG_x	0 = Disabled	
RAMP0_RST	1 = Enabled	Not necessary, but good practice to reset.
RAMP1_RST	0 = Disabled	Do not reset this, or ramp does not work.
RAMP_BURST_COUNT	0	
RAMP_BURST_TRIG	0 = Ramp Transition	

#### Table 17. Sawtooth Ramping Example

#### NOTE

To calculate ramp\_scale\_count and ramp\_dly\_cnt, remember that the desired calibration time is 25 µs.



#### Figure 29. Triangle Waveform Example



#### 7.3.14 SYSREF

The LMX2594 can generate a SYSREF output signal that is synchronized to  $f_{OUT}$  with a programmable delay. This output can be a single pulse, series of pulses, or a continuous stream of pulses. To use the SYSREF capability, the PLL must first be placed in SYNC mode with VCO\_PHASE\_SYNC = 1.

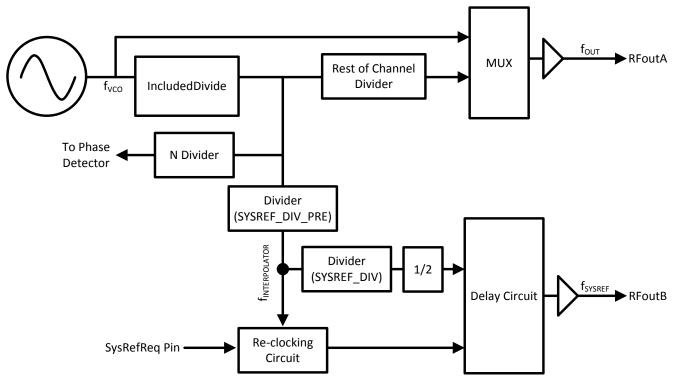


Figure 30. SYSREF Setup

As Figure 30 shows, the SYSREF feature uses IncludedDivide and SYSREF\_DIV\_PRE divider to generate  $f_{INTERPOLATOR}$ . This frequency is used for reclocking of the rising and falling edges at the SysRefReq pin. In master mode, the  $f_{INTERPOLATOR}$  is further divided by 2 × SYSREF\_DIV to generate finite series or continuous stream of pulses.

Table 18. SYSREF Setup	Table	18.	SYSRE	F Setup
------------------------	-------	-----	-------	---------

PARAMETER	MIN	ТҮР	MAX	UNIT
f <sub>VCO</sub>	7.5		15	GHz
finterpolator	0.8		1.5	GHz
IncludedDivide		4 or 6		
SYSREF_DIV_PRE	1, 2, or 4			
SYSREF_DIV	4,6,8, , 4098			
finterpolator	f <sub>INTERPOLATOR</sub> = f <sub>VCO</sub> / (IncludedDivide × SYSREF_DIV_PRE)			
fsysref	$f_{SYSREF} = f_{INTERPOLATOR} / (2 \times SYSREF_DIV)$			
Delay step size		9		ps
Pulses for pulsed mode (SYSREF_PULSE_CNT)	0		15	n/a

The delay can be programmed using the JESD\_DAC1\_CTRL, JESD\_DAC2\_CTRL, JESD\_DAC3\_CTRL, and JESD\_DAC4\_CTRL words. By concatenating these words into a larger word called "SYSREFPHASESHIFT", the relative delay can be found. The sum of these words should always be 63.

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SYSREFPHASESHIFT	DELAY	JESD_DAC1	JESD_DAC2	JESD_DAC3	JESD_DAC4
0	Minimum	36	27	0	0
				0	0
36		0	63	0	0
37		62	1	0	0
99		0	0	63	0
100		0	0	62	1
161		0	0	1	62
162		0	0	0	63
163		1	0	0	62
225		63	0	0	0
226		62	1	0	0
247	Maximum	41	22	0	0
> 247	Invalid	Invalid	Invalid	Invalid	Invalid

## Table 19. SysRef Delay

#### 7.3.14.1 Programmable Fields

Table 20 has the programmable fields for the SYSREF functionality.

FIELD	PROGRAMMING	DEFAULT	DESCRIPTION		
SYSREF_EN	0: Disabled 1: Enabled	0	Enables the SYSREF mode. SYSREF_EN should be 1 if and only if OUTB_MUX = 2 (SysRef).		
SYSREF_DIV_PRE	1: DIV1 2: DIV2 4: DIV4 Other states: invalid		The output of this divider is f <sub>INTERPOLATOR</sub> .		
SYSREF_REPEAT	0: Master mode 1: Repeater mode	0	In master mode, the device creates a series of SYSREF pulses. In repeater mode, SYSREF pulses are generated with the SysRefReq pin.		
SYSREF_PULSE	0: Continuous mode 1: Pulsed mode	0	Continuous mode continuously makes SYSREF pulses, where pulsed mode makes a series of SYSREF_PULSE_CNT pulses.		
SYSREF_PULSE_CNT	0 to 15	4	In the case of using pulsed mode, this is the number of pulses. Setting this to zero is an allowable, but not practical state.		
SYSREF_DIV	0: Divide by 4 1: Divide by 6 2: Divide by 8  2047: Divide by 4098	0	This is one of the dividers between the VCO and SysRef output used in master mode.		

# Table 20. SYSREF Programming Fields

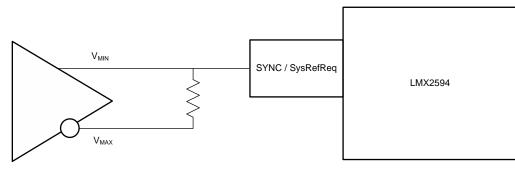
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#### 7.3.14.2 Input and Output Pin Formats

#### 7.3.14.2.1 Input Format for SYNC and SysRefReq Pins

These pins are single-ended, but a differential signal can be converted to drive them. In the LVDS mode, if the INPIN\_FMT is set to LVDS mode, then the bias level can be adjusted with INPIN\_LVL and the hysteresis can be adjusted with INPIN\_HYST.

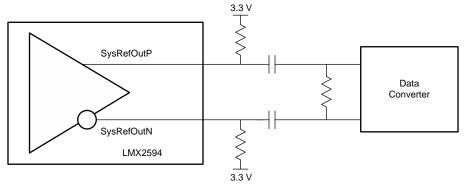


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Figure 31. Driving SYNC/SYSREF With Differential Signal

#### 7.3.14.2.2 SYSREF Output Format

The SYSREF output comes in differential format through RFoutB. This will have a minimum voltage of about 2.3 V and a maximum of 3.3 V. If DC coupling cannot be used, there are two strategies for AC coupling.



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#### Figure 32. SYSREF Output

- 1. Send a series of pulses to establish a DC-bias level across the AC-coupling capacitor.
- 2. Establish a bias voltage at the data converter that is below the threshold voltage by using a resistive divider.



### 7.3.14.3 Examples

The SysRef can be used in a repeater mode (SYSREF\_REPEAT = 1), which just echos the SysRefReq pin, after being reclocked to the  $f_{INTERPOLATOR}$  frequency and then  $f_{OUT}$  (from RFoutA).

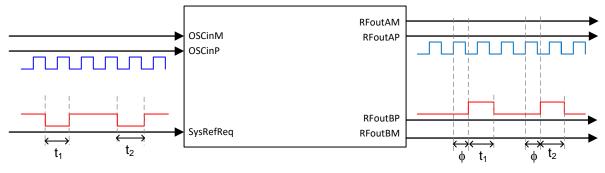


Figure 33. SYSREF Out In Repeater Mode

In master mode (SYSREF\_REPEAT = 0), rising and falling edges at the SysRefReq pin are first reclocked to the  $f_{OSC}$ , then  $f_{INTERPOLATOR}$ , and finally to  $f_{OUT}$ . A programmable number of pulses is generated with a frequency equal to  $f_{VCO}$  / (2 × IncludedDivide × SYSREF\_DIV\_PRE × SYSREF\_DIV). In continuous mode (SYSREF\_PULSE = 0), the SysRefReq pin is held high to generate a continuous stream of pulses. In pulse mode (SYSREF\_PULSE = 1), a finite number of pulses determined by SYSREF\_PULSE\_CNT is sent for each rising edge of the SysRefReq pin.

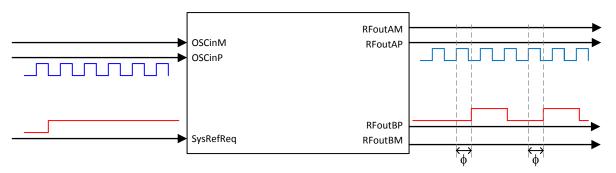


Figure 34. Figure 1. SYSREF Out In Pulsed/Continuous Mode



#### 7.3.14.4 SYSREF Procedure

To use SYSREF, do the these steps:

- 1. Put the device in SYNC mode using the procedure already outlined.
- 2. Figure out IncludedDivide the same way it is done for SYNC mode.
- 3. Calculate the SYSREF\_DIV\_PRE value such that the interpolator frequency ( $f_{INTERPOLATOR}$ ) is in the range of 800 to 1500 MHz.  $f_{INTERPOLATOR} = f_{VCO}$ /IncludedDivide/SYSREF\_DIV\_PRE. Make this frequency a multiple of  $f_{OSC}$  if possible.
- 4. If using continuous mode (SYSREF\_PULSE = 0), ensure the SysRefReq pin is high.
- 5. If using pulse mode (SYSREF\_PULSE = 1), set up the pulse count as desired. Pulses are created by toggling the SysRefReq pin.
- 6. Adjust the delay between the RFoutA and RFoutB signal using the JESD\_DACx\_CTL fields.

### 7.3.15 SysRefReq Pin

The SysRefReq pin can be used in CMOS all the time, or LVDS mode is also optional if SYSREF\_REPEAT = 1. LVDS mode cannot be used in master mode.

### 7.4 Device Functional Modes

Although there are a vast number of ways to configure this device, only one is really functional.

MODE	DESCRIPTION	SOFTWARE SETTINGS
RESET	Registers are held in their reset state. This device does have a power on reset, but it is good practice to also do a software reset if there is any possibility of noise on the programming lines, especially if there is sharing with other devices. Also realize that there are registers not disclosed in the data sheet that are reset as well.	RESET = 1, POWERDOWN = 0
POWERDOWN	Device is powered down.	POWERDOWN = 1 or CE Pin = Low
Normal operating mode	This is used with at least one output on as a frequency synthesizer.	
SYNC mode	This is used where part of the channel divider is in the feedback path to ensure deterministic phase.	VCO_PHASE_SYNC = 1
SYSREF mode	In this mode, RFoutB is used to generate pulses for SYSREF.	VCO_PHASE_SYNC =1, SYSREF_EN = 1

### Table 21. Device Functional Modes

LMX2594

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### 7.5 Programming

The LMX2594 is programmed using 24-bit shift registers. The shift register consists of a R/W bit (MSB), followed by a 7-bit address field and a 16-bit data field. For the R/W bit, 0 is for write, and 1 is for read. The address field ADDRESS[6:0] is used to decode the internal register address. The remaining 16 bits form the data field DATA[15:0]. While CSB is low, serial data is clocked into the shift register upon the rising edge of clock (data is programmed MSB first). When CSB goes high, data is transferred from the data field into the selected register bank. See Figure 1 for timing details.

### 7.5.1 Recommended Initial Power-Up Sequence

For the most reliable programming, TI recommends this procedure::

- 1. Apply power to device.
- 2. Program RESET = 1 to reset registers.
- 3. Program RESET = 0 to remove reset.
- 4. Program registers as shown in the register map in REVERSE order from highest to lowest.
- 5. Wait 10 ms.
- 6. Program register R0 one additional time with FCAL\_EN = 1 to ensure that the VCO calibration runs from a stable state.

### 7.5.2 Recommended Sequence for Changing Frequencies

The recommended sequence for changing frequencies is as follows:

- 1. Change the N-divider value.
- 2. Program the PLL numerator and denominator.
- 3. Program FCAL\_EN (R0[3]) = 1.

### 7.5.3 General Programming Requirements

Follow these requirements when programming the device:

- 1. For register bits that do not have field names in Table 23, it is necessary to program these values just as shown in the register map.
- 2. Not all registers need to be programmed. Refer to Table 22 for details.
- 3. Power-on-reset register values may not be optimal, so it is always necessary to program all of the required registers after powering on the device. Note that the 'Reset' column in register descriptions is the power-on-reset value.

Registers	Function	Comment
R107 – R112	Readback	These registers are for readback only and do not need to be programmed.
R79 – R106	Ramping	If ramping function is not used (RAMP_EN = 0), then these registers do not need to be programmed.
R0 – R78	General	These registers need to be programmed for all scenarios.

#### Table 22. Programming Requirement



# 7.6 Register Maps

												-												
	R/W	A6	A5	A4	A3	A2	A1	A0	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R0	0	0	0	0	0	0	0	0	RAMP _EN	VCO _PH ASE _SY NC	1	0	0	1	OUT _MU TE	FCAL D_/	HPF ADJ		_LPFD .DJ	1	FCA L _EN	MUX OUT _LD_ SEL	RES ET	POW ERD OWN
R1	0	0	0	0	0	0	0	1	0	0	0	0	1	0	0	0	0	0	0	0	1	CAL	CLK_	DIV
R2	0	0	0	0	0	0	1	0	0	0	0	0	0	1	0	1	0	0	0	0	0	0	0	0
R3	0	0	0	0	0	0	1	1	0	0	0	0	0	1	1	0	0	1	0	0	0	0	1	0
R4	0	0	0	0	0	1	0	0			ACA	L_CMP	_DLY				0	1	0	0	0	0	1	1
R5	0	0	0	0	0	1	0	1	0	0	0	0	0	0	0	0	1	1	0	0	1	0	0	0
R6	0	0	0	0	0	1	1	0	1	1	0	0	1	0	0	0	0	0	0	0	0	0	1	0
R7	0	0	0	0	0	1	1	1	0	OUT _FO RCE	0	0	0	0	0	0	1	0	1	1	0	0	1	0
R8	0	0	0	0	1	0	0	0	0	VCO _DA CISE T_F ORC E	1	0	VCO _CA PCT RL_F ORC E	0	0	0	0	0	0	0	0	0	0	0
R9	0	0	0	0	1	0	0	1	0	0	0	OSC _2X	0	1	1	0	0	0	0	0	0	1	0	0
R10	0	0	0	0	1	0	1	0	0	0	0	1			MULT			1	0	1	1	0	0	0
R11	0	0	0	0	1	0	1	1	0	0	0	0				PLI	L_R				1	0	0	0
R12	0	0	0	0	1	1	0	0	0	1	0	1						PLL_F	R_PRE					
R13	0	0	0	0	1	1	0	1	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R14	0	0	0	0	1	1	1	0	0	0	0	1	1	1	1	0	0		CPG		0	0	0	0
R15	0	0	0	0	1	1	1	1	0	0	0	0	0	1	1	0	0	1	0	0	1	1	1	1
R16	0	0	0	1	0	0	0	0	0	0	0	0	0	0	0				VCC	DACI	SET			
R17	0	0	0	1	0	0	0	1	0	0	0	0	0	0	0				VCO_D	ACISE	T_STRT	-		
R18	0	0	0	1	0	0	1	0	0	0	0	0	0	0	0	0	0	1	1	0	0	1	0	0
R19	0	0	0	1	0	0	1	1	0	0	1	0	0	1	1	1			١	/CO_C	APCTR	L		
R20	0	0	0	1	0	1	0	0	1	1	V	'CO_SE	L	VCO _SEL _FO RCE	0	0	0	1	0	0	1	0	0	0
R21	0	0	0	1	0	1	0	1	0	0	0	0	0	1	0	0	0	0	0	0	0	0	0	1

Table 23. Full Register Map

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# Register Maps (continued)

									Table 23	. i un	Negis		ap (cc	minia	cuj									
	R/W	A6	A5	A4	A3	A2	A1	A0	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R22	0	0	0	1	0	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1
R23	0	0	0	1	0	1	1	1	0	0	0	0	0	0	0	0	0	1	1	1	1	1	0	0
R24	0	0	0	1	1	0	0	0	0	0	0	0	0	1	1	1	0	0	0	1	1	0	1	0
R25	0	0	0	1	1	0	0	1	0	0	0	0	1	1	0	0	0	0	1	0	1	0	1	1
R26	0	0	0	1	1	0	1	0	0	0	0	0	1	1	0	1	1	0	1	1	0	0	0	0
R27	0	0	0	1	1	0	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	0
R28	0	0	0	1	1	1	0	0	0	0	0	0	0	1	0	0	1	0	0	0	1	0	0	0
R29	0	0	0	1	1	1	0	1	0	0	1	1	0	0	0	1	1	0	0	0	1	1	0	0
R30	0	0	0	1	1	1	1	0	0	0	1	1	0	0	0	1	1	0	0	0	1	1	0	0
R31	0	0	0	1	1	1	1	1	0	CHDI V _DIV 2	0	0	0	0	1	1	1	1	1	0	1	1	0	0
R32	0	0	1	0	0	0	0	0	0	0	0	0	0	0	1	1	1	0	0	1	0	0	1	1
R33	0	0	1	0	0	0	0	1	0	0	0	1	1	1	1	0	0	0	1	0	0	0	0	1
R34	0	0	1	0	0	0	1	0	0	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 PLL_N[18:16]								:16]						
R35	0	0	1	0	0	0	1	1	0									0						
R36	0	0	1	0	0	1	0	0			PLL_N													
R37	0	0	1	0	0	1	0	1	MASH _SEED _EN	0			PFD_D	LY_SEL	-		0	0	0	0	0	1	0	0
R38	0	0	1	0	0	1	1	0							PLL_	_DEN[3	1:16]							
R39	0	0	1	0	0	1	1	1							PLL	_DEN[1	15:0]							
R40	0	0	1	0	1	0	0	0								[31:16]								
R41	0	0	1	0	1	0	0	1								[15:0]								
R42	0	0	1	0	1	0	1	0							PLL_	_NUM[3	1:16]							
R43	0	0	1	0	1	0	1	1							PLL	_NUM[ <sup>^</sup>	15:0]							
R44	0	0	1	0	1	1	0	0	0	0	$0 \qquad OUTA_PWR \qquad \qquad \begin{array}{c} OUT\\ B_P\\ D\end{array} \begin{array}{c} OUT\\ A_P\\ D\end{array} \begin{array}{c} OUT\\ B_P\\ T_N\end{array} \begin{array}{c} MAS\\ H_R\\ ESE\\ T_N\end{array} \begin{array}{c} 0 \end{array} \begin{array}{c} 0 \end{array} \begin{array}{c} 0 \end{array} MASH_ORDER \end{array}$							DER						
R45	0	0	1	0	1	1	0	1	1	1	0	OUTA	_MUX	OUT	ISET	0	1	1			OUTB	_PWR		
R46	0	0	1	0	1	1	1	0	0	0	0	0	0	1	1	1	1	1	1	1	1	1	OUTB	B_MUX
R47	0	0	1	0	1	1	1	1	0	0	0	0	0	0	1	1	0	0	0	0	0	0	0	0
R48	0	0	1	1	0	0	0	0	0	0	0	0	0	0	1	1	0	0	0	0	0	0	0	0

### Table 23. Full Register Map (continued)

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# Register Maps (continued)

### Table 23. Full Register Map (continued)

	R/W	A6	A5	A4	A3	A2	A1	A0	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R49	0	0	1	1	0	0	0	1	0	1	0	0	0	0	0	1	1	0	0	0	0	0	0	0
R50	0	0	1	1	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R51	0	0	1	1	0	0	1	1	0	0	0	0	0	0	0	0	1	0	0	0	0	0	0	0
R52	0	0	1	1	0	1	0	0	0	0	0	0	1	0	0	0	0	0	1	0	0	0	0	0
R53	0	0	1	1	0	1	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R54	0	0	1	1	0	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R55	0	0	1	1	0	1	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R56	0	0	1	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R57	0	0	1	1	1	0	0	1	0	0	0	0	0	0	0	0	0	0	1	0	0	0	0	0
R58	0	0	1	1	1	0	1	0	INPIN_IGNO RE	INPI N_H YST	INPIN	I_LVL	IN	PIN_FN	1T	0	0	0	0	0	0	0	0	1
R59	0	0	1	1	1	0	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	LD_T YPE
R60	0	0	1	1	1	1	0	0								LD_DL	(							
R61	0	0	1	1	1	1	0	1	0	0 0 0 0 0 0 0 0 1 0 1 0 0 0 0									0					
R62	0	0	1	1	1	1	1	0	0	0	0	0	0	0	1	1	0	0	1	0	0	0	1	0
R63	0	0	1	1	1	1	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R64	0	1	0	0	0	0	0	0	0	0	0	1	0	0	1	1	1	0	0	0	1	0	0	0
R65	0	1	0	0	0	0	0	1	0	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0										0				
R66	0	1	0	0	0	0	1	0	0	0	0	0	0	0	0	1	1	1	1	1	0	1	0	0
R67	0	1	0	0	0	0	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R68	0	1	0	0	0	1	0	0	0	0	0	0	0	0	1	1	1	1	1	0	1	0	0	0
R69	0	1	0	0	0	1	0	1						MA	SH_RS	ST_COL	JNT[31:	16]						
R70	0	1	0	0	0	1	1	0						MA	ASH_R	ST_CO	UNT[15	:0]						
R71	0	1	0	0	0	1	1	1	0	0	0	MASH_RST_COUNT[15:0]       0     0     0     0     SYSREF_DIV_PRE     SYS REF _PUL SE     SYS REF _PUL _EN     SYS REF _REF _RE _EN     0     1												
R72	0	1	0	0	1	0	0	0	0	0	0	0	0					SY	SREF_	DIV		•I		·
R73	0	1	0	0	1	0	0	1	0	0	0	0		JE	SD_DA	C2_CT	RL			JE	SD_DA	C1_CT	RL	
R74	0	1	0	0	1	0	1	0	SYSRE	F_PULS	SE_CN													
R75	0	1	0	0	1	0	1	1	0	0	0	0	1			CHDIV			0	0	0	0	0	0



# Register Maps (continued)

	R/W	A6	A5	A4	A3	A2	A1	A0	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R76	0	1	0	0	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	1	0	0
R77	0	1	0	0	1	1	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R78	0	1	0	0	1	1	1	0	0	0	0	0	RAM P_T HRE SH[3 2]	0	QUIC K_R ECA L_EN			VCC	D_CAP(	CTRL_S	STRT			1
R79	0	1	0	0	1	1	1	1							RAMP_1	THRES	H[31:16	6]						
R80	0	1	0	1	0	0	0	0							RAMP_	THRE	SH[15:0]	]						
R81	0	1	0	1	0	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	RAM P_LI MIT_ HIGH [32]
R82	0	1	0	1	0	0	1	0						R/	AMP_LI	MIT_HI	GH[31:	16]						
R83	0	1	0	1	0	0	1	1						R	AMP_LI	IMIT_H	IGH[15:	0]						
R84	0	1	0	1	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	RAM P_LI MIT_ LOW [32]
R85	0	1	0	1	0	1	0	1						R	AMP_LI	MIT_LC	DW[31:1	6]						
R86	0	1	0	1	0	1	1	0						R	AMP_L	IMIT_L	OW[15:	0]						
R87	0	1	0	1	0	1	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R88	0	1	0	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R89	0	1	0	1	1	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R90	0	1	0	1	1	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R91	0	1	0	1	1	0	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R92	0	1	0	1	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R93	0	1	0	1	1	1	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R94	0	1	0	1	1	1	1	0	0	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0										0				
R95	0	1	0	1	1	1	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R96	0	1	1	0	0	0	0	0	RAMP_BUR ST_EN					F	RAMP_E	BURST	_COUN	Т					0	0
R97	0	1	1	0	0	0	0	1	RAMP0_RS T	0	0	0	1		RAMP_	TRIGE	5		RAMP_	_TRIGA	1	0	RAMF ST_	P_BUR TRIG



# Register Maps (continued)

											5													
	R/W	A6	A5	A4	A3	A2	A1	A0	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R98	0	1	1	0	0	0	1	0						RAMF	P0_INC[	29:16]							0	RAM P0_D LY
R99	0	1	1	0	0	0	1	1							RAM	PO_INC	[15:0]							
R100	0	1	1	0	0	1	0	0							RA	MP0_L	EN							
R101	0	1	1	0	0	1	0	1	0	0	0	0	0	0	0	0	0	RAM P1 _DLY	RAM P1 _RS T	RAM P0 _NE XT	0	0	_N	MP0 EXT RIG
R102	0	1	1	0	0	1	1	0	0	0						R/	AMP1_I	NC[29:	16]			÷		
R103	0	1	1	0	0	1	1	1							RAM	P1_INC	[15:0]							
R104	0	1	1	0	1	0	0	0							RA	MP1_L	EN.							
R105	0	1	1	0	1	0	0	1				RAM	P_DLY	_CNT					RAM P_M ANU AL	RAM P1_N EXT	0	0	RAMI XT_	P1_NE TRIG
R106	0	1	1	0	1	0	1	0	0	0	0	0	0	0	0	0	0	0	0	RAM P_T RIG_ CAL	0	RAM	P_SCAL UNT	E_CO
R107	0	1	1	0	1	0	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R108	0	1	1	0	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R109	0	1	1	0	1	1	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R110	0	1	1	0	1	1	1	0	0	0	0	0	0	rb_LD N	D_VTU IE	0	rb_	_vco_s	SEL	0	0	0	0	0
R111	0	1	1	0	1	1	1	1	0	0	0	0	0	0	0	0			rb	_VCO_(	CAPCT	RL		
R112	0	1	1	1	0	0	0	0	0	0	0	0	0	0	0				rb_V0	CO_DAG	CISET			

### Table 23. Full Register Map (continued)

STRUMENTS

EXAS

### 7.6.1 General Registers R0, R1, & R7

Addre ss	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R0	RAMP _EN	VCO_ PHAS E_SY NC_E N	1	0	0	1	OUT_ MUTE	FCAL_ AI	HPFD_ )J	FCAL_ AI		1	FCAL _EN	MUX OUT_ LD_S EL	RESE T	POW ERDO WN
R1	0	0	0	0	1	0	0	0	0	0	0	0	1	CA	CLK_I	ΟIV
R7	0	OUT_ FORC E	0	0	0	0	0	0	1	0	1	1	0	0	1	0

### Figure 35. Registers Excluding Address

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Location	Field	Туре	Reset	Description
R0[15]	RAMP_EN	R/W	0	0: Disable frequency ramping mode 1: Enable frequency ramping mode
R0[14]	VCO_PHASE_SYNC	R/W	0	0: Disable phase SYNC mode 1: Enable phase SYNC mode
R0[9]	OUT_MUTE	R/W	0	Mute the outputs when the VCO is calibrating. 0: Disabled. If disabled, also be sure to enable OUT_FORCE 1: Enabled. If enabled, also be sure to disable OUT_FORCE
R0[8:7]	FCAL_HPFD_ADJ	R/W		Set this field in accordance to the phase-detector frequency for optimal VCO calibration. 0: $f_{PD} \le 100 \text{ MHz}$ 1: 100 MHz < $f_{PD} \le 150 \text{ MHz}$ 2: 150 MHz < $f_{PD} \le 200 \text{ MHz}$ 3: $f_{PD} > 200 \text{ MHz}$
R0[6:5]	FCAL_LPFD_ADJ	R/W	0	Set this field in accordance to the phase detector frequency for optimal VCO calibration. 0: $f_{PD} \ge 10 \text{ MHz}$ 1: 10 MHz > $f_{PD} \ge 5 \text{ MHz}$ 2: 5 MHz > $f_{PD} \ge 2.5 \text{ MHz}$ 3: $f_{PD} < 2.5 \text{ MHz}$
R0[3]	FCAL_EN	R/W	0	Enable the VCO frequency calibration. Also note that the action of programming this bit to a 1 activates the VCO calibration
R0[2]	MUXOUT_LD_SEL	R/W	0	Selects the state of the function of the MUXout pin 0: Readback 1: Lock detect
R0[1]	RESET	R/W	0	Resets and holds all state machines and registers to default value. 0: Normal operation 1: Reset
R0[0]	POWERDOWN	R/W	0	Powers down entire device 0: Normal operation 1: Powered down
R1[2:0]	CAL_CLK_DIV	R/W	3	Sets divider for VCO calibration state machine clock based on input frequency. 0: Divide by 1. Use for $f_{OSC} \le 200 \text{ MHz}$ 1: Divide by 2. Use for $f_{OSC} \le 400 \text{ MHz}$ 2: Divide by 4. Use for $f_{OSC} \le 800 \text{ MHz}$ 3: Divide by 8. All $f_{OSC}$
				If user is not concerned with lock time, it is recommended to set this value to 3. By slowing down the VCO calibration, the best and most repeatable VCO phase noise can be attained
R7[14]	OUT_FORCE	R/W	0	Works with OUT_MUTE in disabling outputs when VCO calibrating.

# Table 24. Field Descriptions



#### 7.6.2 Input Path Registers

	-			-			-				r					
	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R9	0	0	0	OSC_ 2X	0	1	1	0	0	0	0	0	0	1	0	0
R10	0	0	0	1			MULT			1	0	1	1	0	0	0
R11	0	0	0	0				PLI	R				1	0	0	0
R12	0	1	0	1						PLL_F	R_PRE					

### Figure 36. Registers Excluding Address

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Location	Field	Туре	Reset	Description
R9[12]	OSC_2X	R/W	0	Low=noise OSCin frequency doubler. 0: Disabled 1: Enabled
R10[11:7]	MULT	R/W	1	Programmable input frequency multiplier 0,2,,8-31: Reserved 1: Byapss 3: 3X  7: 7X
R11[11:4]	PLL_R	R/W	1	Programmable input path divider after the programmable input frequency multiplier.
R12[11:0]	PLL_R_PRE	R/W	1	Programmable input path divider before the programmable input frequency multiplier.

### Table 25. Field Descriptions

### 7.6.3 Charge Pump Registers (R13, R14)

### Figure 37. Registers Excluding Address

	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R14	0	0	0	1	1	1	1	0	0		CPG		0	0	0	0

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

### Table 26. Field Descriptions

Location	Field	Туре	Reset	Description
R14[6:4]	CPG	R/W	7	Effective charge-pump current. This is the sum of up and down currents. 0: 0 mA 1: 6 mA 2: Reserved 3: 12 mA 4: 3 mA 5: 9 mA 6: Reserved 7: 15 mA

# 7.6.4 VCO Calibration Registers

	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R4				ACAL_C	CMP_DL	Y			0	1	0	0	0	0	1	1
R8	0	VCO_ DACI SET_ FORC E	1	0	VCO_ CAPC TRL_ FORC E	0	0	0	0	0	0	0	0	0	0	0
R16	0	0	0	0	0	0	0				VCC	DACIS	SET			
R17	0	0	0	0	0	0	0				VCO_D	ACISET	_STRT			
R19	0	0	1	0	0	1	1	1				VCO_C/	APCTRL			
R20	1	1	١	/CO_SE	L	VCO_ SEL_ FORC E	0	0	0	1	0	0	1	0	0	0

### Figure 38. Registers Excluding Address

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

### Table 27. Field Descriptions

Location	Field	Туре	Reset	Description
R4[15:8]	ACAL_CMP_DELAY	R/W	10	VCO amplitude calibration delay. Lowering this value can speed up VCO calibration, but lowering it too much may degrade VCO phase noise. The minimum allowable value for this field is 10 and this allows the VCO to calibrate to the correct frequency for all scenarios. To yield the best and most repeatable VCO phase noise, this relationship should be met: ACAL_CMP_DLY > Fsmclk / 10 MHz, where Fsmclk = Fosc / $2^{CAL_CLK_DIV}$ and Fosc is the input reference frequency. If calibration time is of concern, then it is recommended to set this register to $\geq$ 25.
R8[14]	VCO_DACISET_FORCE	R/W	0	This forces the VCO_DACISET value
R8[11]	VCO_CAPCTRL_FORCE	R/W	0	This forces the VCO_CAPCTRL value
R16[8:0]	VCO_DACISET	R/W	128	This sets the final amplitude for the VCO calibration in the case that amplitude calibration is forced.
R17[8:0]	VCO_DACISET_STRT	R/W	250	This sets the initial starting point for the VCO amplitude calibration.
R19[7:0]	VCO_CAPCTRL	R/W	183	This sets the final VCO band when VCO_CAPCTRL is forced.
R20[13:11]	VCO_SEL	R/W	7	This sets VCO start core for calibration and the VCO when it is forced. 0: Not Used 1: VCO1 2: VCO2 3: VCO3 4: VCO4 5: VCO5 6: VCO6 7: VCO7
R20[10]	VCO_SEL_FORCE	R/W	0	This forces the VCO to use the core specified by VCO_SEL. It is intended mainly for diagnostic purposes. 0: Disabled (recommended) 1: Enabled



### 7.6.5 N Divider, MASH, and Output Registers

	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R34	0	0	0	0	0	0	0	0	0	0	0	0	0	PL	L_N[18:	16]
R36								PLI	N							
R37	MASH _SEE _D _EN	0			PFD_DI	LY_SEL			0	0	0	0	0	1	0	0
R38									N[31:16]							
R39					PLL_DEN[15:0]											
R40							[31:16]									
R41								[15	5:0]							
R42								PLL_NU	M[31:16]							
R43								PLL_NU	JM[15:0]							
R44	0	0			OUTA	_PWR			OUTB _PD	OUTA _PD	MASH _RES ET_N	0	0	MA	SH_ORE	DER
R45	1 1 0 OUTA_MUX OUT_ISET							0	1	1			OUTB	_PWR		
R46	0	0	0	0	0	1	1	1	1	1	1	1	1	1	OUTB	_MUX

### Figure 39. Registers Excluding Address

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

### Table 28. Field Descriptions

Location	Field	Туре	Reset	Description
R34[2:0] R36[15:0]	PLL_N	R/W	100	The PLL_N divider value is in the feedback path and divides the VCO frequency.
R37[15]	MASH_SEED_EN	R/W	0	Enabling this bit allows the to be applied to shift the phase at the output or optimize spurs.
R37[13:8]	PFD_DLY_SEL	R/W	2	The PFD_DLY_SEL must be adjusted in accordance to the N- divider value. This is with the functional description for the N- divider.
R38[15:0] R39[15:0]	PLL_DEN	R/W	42949672 95	The fractional denominator.
R40[15:0] R41[15:0]	MASH_SEED	R/W	0	The initial state of the MASH engine first accumulator. Can be used to shift phase or optimize fractional spurs. Every time the field is programmed, it ADDS this MASH seed to the existing one. To reset it, use the MASH_RESET_N bit.
R42[15:0] R43[15:0]	PLL_NUM	R/W	0	The fractional numerator
R44[13:8]	OUTA_PWR	R/W	31	Adjusts output power. Higher numbers give more output power to a point, depending on the pullup component used.
R44[7]	OUTB_PD	R/W	1	Powers down output B 0: Output B active 1: Output B powered down
R44[6]	OUTA_PD	R/W	0	Powers down output A 0: Output A Active 1: Output A powered down
R44[5]	MASH_RESET_N	R/W	1	Resets MASH circuitry to an initial state 0: MASH held in reset. All fractions are ignored 1: Fractional mode enabled. MASH is NOT held in reset.
R44[2:0]	MASH_ORDER	R/W	0	Sets the MASH order 0: Integer mode 1: First order modulator 2: Second order modulator 3: Third order modulator 4: Fourth order modulator 5-7: Reserved

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Location	Field	Туре	Reset	Description
R45[12:11]	OUTA_MUX	R/W	1	Selects what signal goes to RFoutA 0: Channel divider 1: VCO 2: Reserved 3: High impedance
R45[10:9]	OUT_ISET	R/W	0	Setting to a lower value allows slightly higher output power at higher frequencies at the expense of higher current consumption. 0: Maximum output power boost  3: No output power boost
R45[5:0]	OUTB_PWR	R/W	31	Output power setting for RFoutB.
R46[1:0]	OUTB_MUX	R/W	1	Selects what signal goes to RFoutB 0: Channel divider 1: VCO 2: SysRef (also ensure SYSREF_EN=1) 3: High impedance

### Table 28. Field Descriptions (continued)

# 7.6.6 SYNC and SysRefReq Input Pin Register

# Figure 40. Registers Excluding Address

	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R58	INPIN _IGN ORE	INPIN _HYS T	INPIN	I_LVL	IN	IPIN_FM	IT	0	0	0	0	0	0	0	0	1

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

# Table 29. Field Descriptions

Location	Field	Туре	Reset	Description
R58[15]	INPIN_IGNORE	R/W	1	Ignore SYNC and SysRefReq Pins 0: Pins are used. Only valid for VCO_PHASE_SYNC = 1 1: Pin is ignored
R58[14]	INPIN_HYST	R/W	0	High Hysteresis for LVDS mode 0: Disabled 1: Enabled
R58[13:12]	INPIN_LVL	R/W	0	Sets bias level for LVDS mode. In LVDS mode, a voltage divider can be inserted to reduce susceptibility to common-mode noise of an LVDS line because the input is single-ended. With a reasonable setup, TI recommends using INPIN_LVL = 1 (Vin) to use the entire signal swing of an LVDS line. 0: Vin/4 1: Vin 2: Vin/2 3: Invalid
R58[11:9]	INPIN_FMT	R/W	0	0: SYNC = SysRefReq = CMOS 1: SYNC = LVDS, SysRefReq=CMOS 2: SYNC = CMOS, SysRefReq = LVDS 3: SYNC = SysRefReq = LVDS 4: Invalid 5: Invalid 6: Invalid 7: Invalid



#### 7.6.7 Lock Detect Registers

	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R59	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	LD_T YPE
R60								LD_	DLY							

### Figure 41. Registers Excluding Address

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

### Table 30. Field Descriptions

Location	Field	Туре	Reset	Description
R59[0]	LD_TYPE	R/W	1	Lock detect type 0: VCO calibration status 1: VCO calibration status and Indirect Vtune
R60[15:0]	LD_DLY	R/W	1000	Lock Detect Delay. This is the delay added to the lock detect after the VCO calibration is successful and before the lock detect is asserted high. The delay added is in phase-detector cycles. If set to 0, the lock detect immediately becomes high after the VCO calibration is successful.

### 7.6.8 MASH\_RESET

#### Figure 42. Registers Excluding Address

	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R69							MASH	I_RST_0	COUNT[	31:16]						
R70							MAS	H_RST_	COUNT	[15:0]						

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

### Table 31. Field Descriptions

Location	Field	Туре	Reset	Description
R69[15:0] R70[15:0]	MASH_RST_COUNT	R/W	50000	If the designer does not use this device in fractional mode with VCO_PHASE_SYNC = 1, then this field can be set to 0. In phase-sync mode with fractions, this bit is used so that there is a delay for the VCO divider after the MASH is reset. This delay must be set to greater than the lock time of the PLL. It does impact the latency time of the SYNC feature.

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### 7.6.9 SysREF Registers

	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R71	0	0	0	0	0	0	0	0	SYSF	REF_DIV	_PRE	SYSR EF_P ULSE	SYSR EF_E N	SYSR EF_R EPEA T	0	1
R72	0	0	0	0	0					SY	SREF_	DIV				
R73	0	0	0	0		JI	ESD_DA	C2_CTF	RL			JI	ESD_DA	C1_CTR	۲L.	
R74	SY	SREF_P	ULSE_C	NT		JESD_DAC4_CTRL						JI	ESD_DA	C3_CTR	L	

### Figure 43. Registers Excluding Address

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

# Table 32. Field Descriptions

Location	Field	Туре	Reset	Description
R71[7:5]	SYSREF_DIV_PRE	R/W	4	Pre-divider for SYSREF 1: Divide by 1 2: Divide by 2 4: Divide by 4 All other states: invalid
R71[4]	SYSREF_PULSE	R/W	0	Enable pulser mode in master mode 0: Disabled 1: Enabled
R71[3]	SYSREF_EN	R/W	0	Enable SYSREF
R71[2]	SYSREF_REPEAT	R/W	0	Enable repeater mode 0: Master mode 1: Repeater mode
R72[10:0]	SYSREF_DIV	R/W	0	Divider for the SYSREF 0: Divide by 4 1: Divide by 6 2: Divide by 8  2047: Divide by 4098
R73[5:0]	JESD_DAC1_CTRL	R/W	63	These are the adjustments for the delay for the SYSREF. Two of
R73[11:6]	JESD_DAC2_CTRL	R/W	0	these must be zero and the other two values must sum to 63.
R74[5:0]	JESD_DAC3_CTRL	R/W	0	
R74[11:6]	JESD_DAC4_CTRL	R/W	0	
R74[15:12]	SYSREF_PULSE_CNT	R/W	0	Number of pulses in pulse mode in master mode



# 7.6.10 CHANNEL Divider Registers

Reg	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
R31	0	CHDIV _DIV2	0	0	0	0	1	1	1	1	1	0	1	1	0	0
R75	0	0	0	0	1			CHDIV			0	0	0	0	0	0

Figure 44. Registers Excluding Address

		14510		Descriptions	
Location	Field	Туре	Reset	Description	
R31[14]	SEG1_EN	R/W	0	Enable driver buffer for CHDIV > 2 0: Disabled (only valid for CHDIV = 2) 1: Enabled (use for CHDIV > 2)	
R75[10:6]	CHDIV	R/W	0	VCO divider value 0: 2 1: 4 2: 6 3: 8 4: 12 5: 16 6: 24 7: 32 8: 48 9: 64 10: 72 11: 96 12: 128 13: 192 14: 256 15: 384 16: 512 17: 768 18-31: Reserved	

### Table 33. Field Descriptions

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### 7.6.11 Ramping and Calibration Fields

	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R78	0	0	0	0	RAMP _THR ESH[3 2]	0	QUIC K_RE CAL_ EN			VC	O_CAPO	CTRL_S	TRT			1
R79							RAI	MP_THR	ESH[31	:16]						
R80	RAMP_THRESH[15:0]															

### Figure 45. Registers Excluding Address

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

### Table 34. Field Descriptions

Location	Field	Туре	Reset	Description
R78[11] R79[15:0] R80[15:0]	RAMP_THRESH	R/W	0	This sets how much the ramp can change the VCO frequency before calibrating. If this frequency is chosen to be $\Delta f$ , then it is calculated as follows: RAMP_THRESH = ( $\Delta f / f_{PD}$ ) × 16777216
R78[9]	QUICK_RECAL_EN	R/W	0	Causes the initial VCO_CORE, VCO_CAPCTRL, and VCO_DACISET to be based on the last value. Useful if the frequency change is small, as is often the case for ramping. 0: Disabled 1: Enabled
R78[8:1]	VCO_CAPCTRL_STRT	R/W	0	This sets the initial value for VCO_CAPCTRL if not overridden by other settings. Smaller values yield a higher frequency band within a VCO core. Valid number range is 0 to 183.



#### 7.6.12 Ramping Registers

These registers are only relevant for ramping functions and are enabled if and only if RAMP\_EN (R0[15]) = 1.

### 7.6.12.1 Ramp Limits

	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R81	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	RAMP _LIMI T_HIG H[32]
R82							RAM	P_LIMIT	_HIGH[3	31:16]						
R83							RAM	IP_LIMIT	[_HIGH	15:0]						
R84	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	RAMP _LIMI T_LO W[32]
R85		RAMP_LIMIT_LOW[31:16]														
R86	RAMP_LIMIT_LOW[15:0]															

### Figure 46. Registers Excluding Address

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

### Table 35. Field Descriptions

Location	Field	Туре	Reset	Description
R81[0] R82[15:0] R83[15:0]	RAMP_LIMIT_HIGH	R/W	0	This sets a maximum frequency that the ramp can not exceed so that the VCO does not get set beyond a valid frequency range. Suppose $f_{HIGH}$ is this frequency and $f_{VCO}$ is the starting VCO frequency then: For $f_{HIGH} \ge f_{VCO}$ : RAMP_LIMIT_HIGH = $(f_{HIGH} - f_{VCO})/f_{PD} \times 16777216$ For $f_{HIGH} < f_{VCO}$ this is not a valid condition to choose.
R84[0] R85[15:0] R86[15:0]	RAMP_LIMIT_LOW	R/W	0	This sets a minimum frequency that the ramp can not exceed so that the VCO does not get set beyond a valid frequency range. Suppose $f_{LOW}$ is this frequency and $f_{VCO}$ is the starting VCO frequency then: For $f_{LOW} \le f_{VCO}$ : RAMP_LIMIT_LOW = $2^{33} - 16777216 \times (f_{VCO} - f_{LOW}) / f_{PD}$ For $f_{LOW} > f_{VCO}$ , this is not a valid condition to choose.

# 7.6.12.2 Ramping Triggers, Burst Mode, and RAMP0\_RST

### Figure 47. Registers Excluding Address

	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R96	RAMP _BUR ST_E N						RAMP_	BURST_	COUNT						0	0
R97	RAMP 0_RS T	0	0	0	1		RAMP_	_TRIGB			RAMP_	_TRIGA		0	RAMP_ T_T	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

# Table 36. Field Descriptions

Location	Field	Туре	Reset	Description
R96[15]	RAMP_BURST_EN	R/W	0	Enables burst ramping mode. In this mode, a RAMP_BURST_COUNT ramps are sent out when RAMP_EN is set from 0 to 1. 0: Disabled 1: Enabled
RAMP96[1 4:2]	RAMP_BURST_COUNT	R/W	0	Sets how many ramps are run in burst ramping mode.
R97[15]	RAMP0_RST	R/W	0	Resets RAMP0 at start of ramp to eliminate round-off errors. Must only be used in automatic ramping mode. 0: Disabled 1: Enabled
R97[6:3]	RAMP_TRIGA	R/W	0	Multipurpose Trigger A definition: 0: Disabled 1: RampClk pin rising edge 2: RampDir pin rising edge 4: Always triggered 9: RampClk pin falling edge 10: RampDir pin falling edge All other states: reserved
R97[10:7]	RAMP_TRIGB	R/W	0	Multipurpose trigger B definition: 0: Disabled 1: RampClk pin Rising Edge 2: RampDir pin Rising Edge 4: Always Triggered 9: RampClk pin Falling Edge 10: RampDir pin Falling Edge All other states: Reserved
R97[1:0]	RAMP_BURST_TRIG	R/W	0	Ramp burst trigger definition that triggers the next ramp in the count. Note that RAMP_EN starts the count, not this word. 0: Ramp Transition 1: Trigger A 2: Trigger B 3: Reserved

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### 7.6.12.3 Ramping Configuration

	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R98						R	AMP0_I	NC[29:1	6]						0	RAMP 0_DL Y
R99							F	RAMP0_	INC[15:0	<b>)</b> ]						
R100								RAMP	0_LEN		-					
R101	0	0	0	0	0	0	0	0	0	RAMP 1 _DLY	RAMP 1 _RST	RAMP 0 _NEX T	0	0		/IP0_ _TRIG
R102	0	0						F	RAMP1_I	NC[29:1	6]					
R103							F	RAMP1_	INC[15:0	D]						
R104								RAMP	1_LEN							
R105		RAMP1_LEN       RAMP_DLY_CNT     RAMP     RAMP       _MAN     _MAN     0     0       _NEX     _NEX     0     0														
R106	0	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0														

Figure 48. Registers Excluding Address

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

### Table 37. Field Descriptions

Location	Field	Туре	Reset	Description		
R98[15:2] R99[15:0]	RAMP0_INC	R/W	0	2's complement of the amount the RAMP0 is incremented in phase detector cycles.		
R98[0]	RAMP0_DLY	_DLY R/W 0 Enabling this bit uses two clocks instead of a ramp. Effectively doubling the length. 0: Normal ramp length 1: Double ramp length				
R100[15:0]	RAMP0_LEN	R/W	0	Length of RAMP0 in phase detector cycles		
R101[6]	RAMP1_DLY         R/W         0         Enabling this bit uses two clocks instead of one to ramp. Effectively doubling the length. 0: Normal ramp length 1: Double ramp length					
R101[5]						
R101[4]	RAMP0_NEXT	R/W	0	Defines what ramp comes after RAMP0 0: RAMP0 1: RAMP1		
R101[1:0]	RAMP0_NEXT_TRIG	R/W	0	Defines what triggers the next ramp 0: RAMP0_LEN timeout counter 1: Trigger A 2: Trigger B 3: Reserved		
R102[13:0] R103[15:0]	RAMP1_INC	R/W	0	2's complement of the amount the RAMP1 is incremented in phase detector cycles.		
R104[15:0]	RAMP1_LEN	R/W	0	Length of RAMP1 in phase detector cycles		
R105[15:6]	RAMP_DLY_CNT	R/W	0	This is the number of state machine clock cycles for the VCO calibration in automatic mode. If the VCO calibration is less, then it is this time. If it is more, then the time is the VCO calibration time.		
R105[5]	RAMP_MANUAL	R/W	0	Enables manual ramping mode, or otherwise automatic mode 0: Automatic ramping mode 1: Manual ramping mode		

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### Table 37. Field Descriptions (continued)

Location	Field	Туре	Reset	Description			
R105[4]	RAMP1_NEXT	R/W	V 0 Determines what ramp comes after RAMP1: 0: RAMP0 1: RAMP1				
R105[1:0]	RAMP1_NEXT_TRIG	R/W	0	Defines what triggers the next ramp 0: RAMP1_LEN timeout counter 1: Trigger A 2: Trigger B 3: Reserved			
R106[4]	RAMP_TRIG_CAL	R/W	0	Enabling this bit forces the VCO to calibrate after the ramp.			
R106[2:0]	RAMP_SCALE_COUNT	R/W	7	Multiplies RAMP_DLY count by 2 <sup>RAMP_SCALE_COUNT</sup>			

### 7.6.13 Readback Registers

### Figure 49. Registers Excluding Address

	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
R110	0	0	0	0	0	rb_ VTl	LD_ JNE	0	rb_VCO_SEL		0	0	0	0	0	
R111	0	0	0	0	0	0	0	0	0 rb_VCO_CAPCTRL							
R112	0	0	0	0	0	0	0	rb_VCO_DACISET								

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

# Table 38. Field Descriptions

Location	Field	Туре	Reset	Description
R110[10:9]	rb_LD_VTUNE	R	0	Readback of Vtune lock detect 0: Unlocked (Vtune low) 1: Invalid State 2: Locked 3: Unlocked (Vtune High)
R110[7:5]	rb_VCO_SEL	R	0	Reads back the actual VCO that the calibration has selected. 0: Invalid 1: VCO1  7: VCO7
R111[7:0]	rb_VCO_CAPCTRL	R	183	Reads back the actual CAPCTRL capcode value the VCO calibration has chosen.
R112[8:0]	rb_VCO_DACISET	R	170	Reads back the actual amplitude (DACISET) value that the VCO calibration has chosen.



### 8 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

### 8.1.1 OSCin Configuration

The OSCin supports single-ended or differential clocks. There must be a AC-coupling capacitor in series before the device pin. The OSCin inputs are high-impedance CMOS with internal bias voltage. TI recommends putting termination shunt resistors to terminate the differential traces (if there are  $50-\Omega$  characteristic traces, place  $50-\Omega$  resistors). The OSCin and OSCin\* side should be matched in layout. A series AC-coupling capacitors should immediately follow OSCin pins in the board layout, then the shunt termination resistors to ground should be placed after.

Input clock definitions are shown in Figure 50:

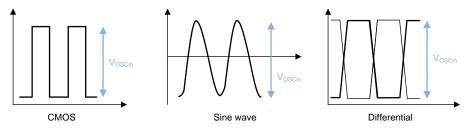


Figure 50. Input Clock Definitions

### 8.1.2 OSCin Slew Rate

The slew rate of the OSCin signal can impact the spurs and phase noise of the LMX2594 if it is too low. In general, a high slew rate and a lower amplitude signal, such as LVDS, can give best performance.

#### 8.1.3 RF Output Buffer Power Control

The OUTA\_PWR and OUTB\_PWR registers can be used to control the output power of the output buffers. The setting for optimal power may depend on the pullup component, but is typically around 50. The higher the setting, the higher the current consumption of the output buffer.

### 8.1.4 RF Output Buffer Pullup

The choice of output buffer components is very important and can have a profound impact on the output power. Table 39 shows how to treat each pin. If using a single-ended output, a pullup is required, and the user can put a  $50-\Omega$  resistor after the capacitor.



# **Application Information (continued)**

# Table 39. Different Methods for Pullup on Outputs

PULLUP STYLE	DIAGRAM	COMMENTS
Inductor	RFoutAP	Potentially higher output power, but output impedance is far from 50 $\Omega$ . Consider also using with a resistive pad.
Resistor	RFoutAP	More consistent matching

# Table 40. Output Pullup Configuration

COMPONENT	VALUE	PART NUMBER
Inductor	Varies with frequency	
Resistor	50 Ω	Vishay FC0402E50R0BST1
Capacitor	Varies with frequency	ATC 520L103KT16T ATC 504L50R0FTNCFT

# 8.2 Typical Application

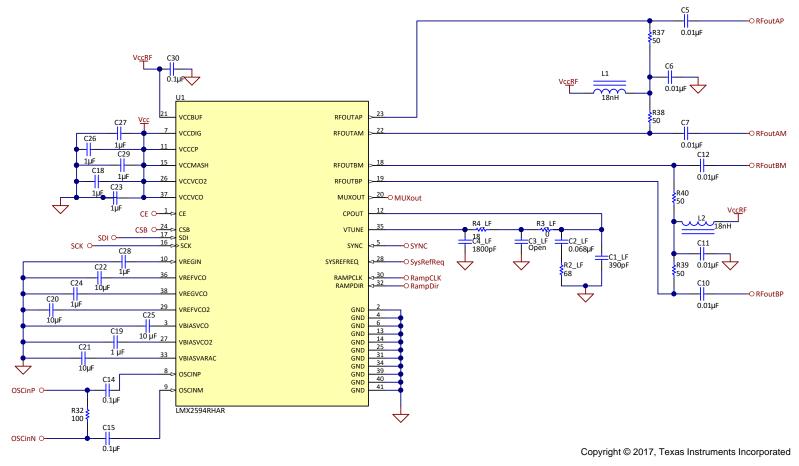


Figure 51. Typical Application Schematic



### 8.2.1 Design Requirements

The design of the loop filter is complex and is typically done with software. The PLLATINUM<sup>™</sup> Sim software is an excellent resource for doing this and the design is shown in the Figure 52. For those interested in the equations involved, the *PLL Performance, Simulation, and Design Handbook* listed in the end of this document goes into great detail as to the theory and design of PLL loop filters.

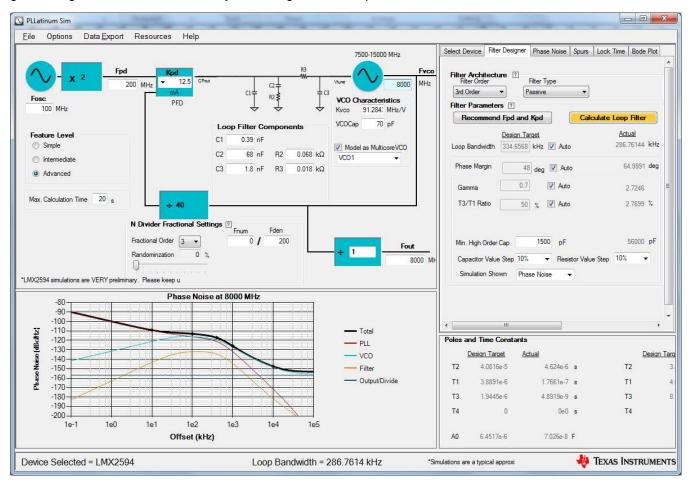


Figure 52. PLLATINUM™ Sim Design Screen

### 8.2.2 Detailed Design Procedure

The integration of phase noise over a certain bandwidth (jitter) is an performance specification that translates to signal-to-noise ratio. Phase noise inside the loop bandwidth is dominated by the PLL, while the phase noise outside the loop bandwidth is dominated by the VCO. Generally, jitter is lowest if the loop bandwidth is designed to the point where the two intersect. A higher phase margin loop filter design has less peaking at the loop bandwidth and thus lower jitter. The tradeoff with this is that longer lock times and spurs must be considered in design as well.



#### 8.2.3 Application Curve

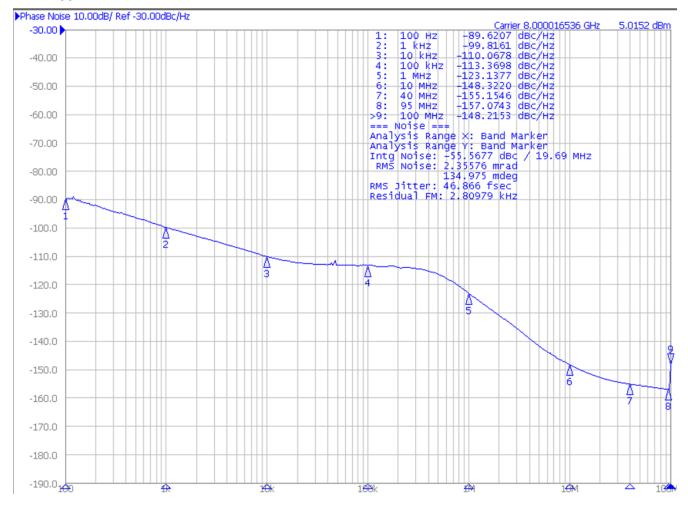


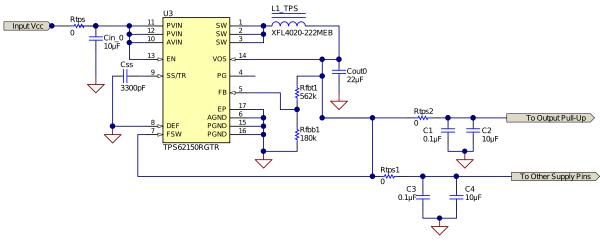
Figure 53. Typical Jitter



### 9 Power Supply Recommendations

If fractional spurs are a large concern, using a ferrite bead to each of these power supply pins can reduce spurs to a small degree. This device has integrated LDOs, which improves the resistance to power supply noise. However, the pullup components on the RFoutA and RFoutB pins on the outputs have a direct connection to the power supply, take extra care to ensure that the voltage is clean for these pins. *Figure 54* is a typical application example.

This device can be powered by an external DC-DC buck converter, such as the TPS62150. Note that although Rtps, Rtps1, and Rtps2 are 0  $\Omega$  in the schematic, they could be potentially replaced with a larger resistor value or inductor value for better power supply filtering.



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### Figure 54. Using the TPS62150 as a Power Supply

For DC bias levels, refer to .

Pin Number	Pin Name	Bias Level <sup>(1)</sup>
3	VBIASVCO	1.3
27	VBIASVCO2	0.7
29	VREFVCO2	2.9
33	VBIASVARAC	1.7
36	VREFVCO	2.9
38	VREGVCO	2.1

(1) The bias level is measured after following Recommended Initial Power-Up Sequence.



## 10 Layout

### **10.1 Layout Guidelines**

In general, the layout guidelines are similar to most other PLL devices. Here are some specific guidelines.

- GND pins may be routed on the package back to the DAP.
- The OSCin pins are internally biased and must be AC-coupled.
- If not used, RampClk, RampDir, and SysRefReq can be grounded to the DAP.
- For the Vtune pin, try to place a loop filter capacitor as close as possible to the pin. This may mean separating the capacitor from the rest of the loop filter.
- For the outputs, keep the pullup component as close as possible to the pin and use the same component on each side of the differential pair.
- If a single-ended output is needed, the other side must have the same loading and pullup. However, the routing for the used side can be optimized by routing the complementary side through a via to the other side of the board. On this side, use the same pullup and make the load look equivalent to the side that is used.
- Ensure that DAP on device is well-grounded with many vias, preferably copper filled.
- Have a thermal pad that is as large as the LMX2594 exposed pad. Add vias to the thermal pad to maximize thermal performance.
- Use a low loss dielectric material, such as Rogers 4003, for optimal output power.
- See instructions for the LMX2594EVM (*LMX2594 EVM Instructions, 15 GHz Wideband Low Noise PLL With Integrated VCO*) for more details on layout.



# 10.2 Layout Example

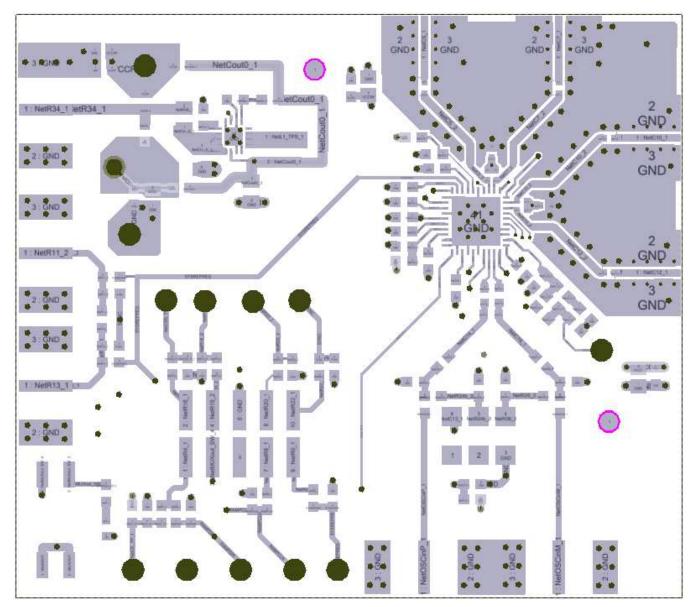


Figure 55. LMX2594 PCB Layout



# 11 Device and Documentation Support

### 11.1 Device Support

### 11.1.1 Third-Party Products Disclaimer

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### 11.1.2 Development Support

Texas Instruments has several software tools to aid in the development at www.ti.com. Among these tools are:

- EVM software to understand how to program the device and for programming the EVM board.
- EVM board instructions for seeing typical measured data with detailed measurement conditions and a complete design.
- PLLatinum Sim program for designing loop filters, simulating phase noise, and simulating spurs .

### **11.2 Documentation Support**

### 11.2.1 Related Documentation

For related documentation see the following:

- AN-1879 Fractional N Frequency Synthesis (SNAA062)
- *PLL Performance, Simulation, and Design Handbook* (SNAA106)
- LMX2594 EVM Instructions –15-GHz Wideband Low Noise PLL With Integrated VCO (SNAU210)

### 11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### **11.4 Community Resources**

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E<sup>™</sup> Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support TI's Design Support** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 11.5 Trademarks

PLLATINUM, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

#### **11.6 Electrostatic Discharge Caution**



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 11.7 Glossary

#### SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.



# 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



2-Apr-2019

# PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
LMX2594RHAR	ACTIVE	VQFN	RHA	40	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-3-260C-168 HR	-40 to 85	LMX2594	Samples
LMX2594RHAT	ACTIVE	VQFN	RHA	40	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-3-260C-168 HR	-40 to 85	LMX2594	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

2-Apr-2019

# PACKAGE MATERIALS INFORMATION

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# TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*A	l dimensions are nominal												
	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	LMX2594RHAR	VQFN	RHA	40	2500	330.0	16.4	6.3	6.3	1.5	12.0	16.0	Q1
	LMX2594RHAT	VQFN	RHA	40	250	178.0	16.4	6.3	6.3	1.5	12.0	16.0	Q1

TEXAS INSTRUMENTS

www.ti.com

# PACKAGE MATERIALS INFORMATION

2-Apr-2019



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMX2594RHAR	VQFN	RHA	40	2500	367.0	367.0	38.0
LMX2594RHAT	VQFN	RHA	40	250	210.0	185.0	35.0

# **MECHANICAL DATA**



All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α.

- Β. This drawing is subject to change without notice.
- QFN (Quad Flatpack No-Lead) Package configuration. C.
- The package thermal pad must be soldered to the board for thermal and mechanical performance. D.
- See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions. Ε.
- F. Package complies to JEDEC MO-220 variation VJJD-2.



# RHA (S-PVQFN-N40)

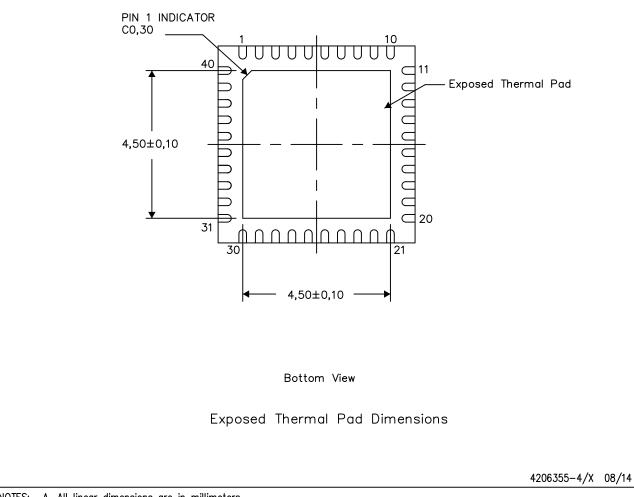
# PLASTIC QUAD FLATPACK NO-LEAD

### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

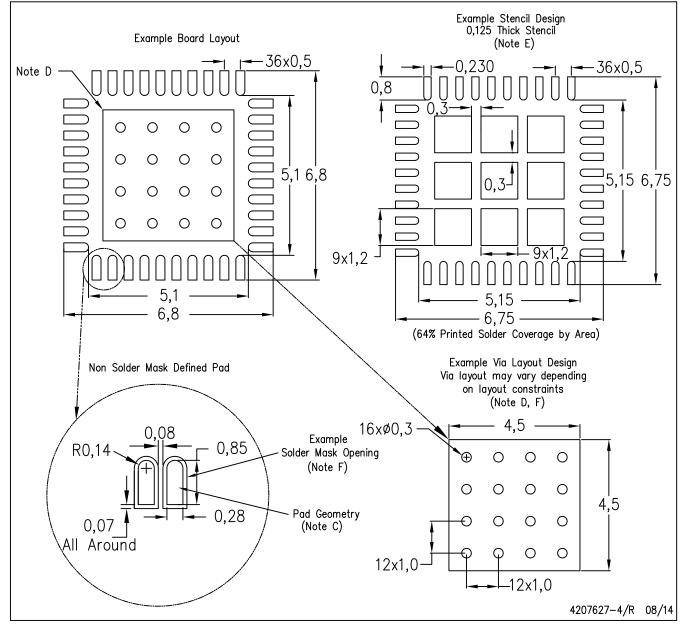


#### NOTES: A. All linear dimensions are in millimeters





PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.



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